

TLIN2024A-Q1 Quad Local Interconnect Network (LIN) Transceiver with Dominant State Timeout

1 Features

- AEC-Q100 (Grade1) Qualified for automotive applications
- Compliant to LIN2.0, LIN2.1, LIN2.2, LIN2.2A and ISO/DIS 17987–4 electrical physical layer (EPL) specification
- Compliant to SAE J2602-1 LIN network for vehicle applications
- **Functional Safety-Capable**
 - Documentation available to aid in functional safety system design
- Supports 12-V and 24-V battery applications
- LIN transmit data rate up to 20 kbps
- LIN receive data rate up to 100 kbps
- Wide operational supply voltage range: 4 V to 48 V
- Sleep mode: ultra-low current consumption allows wake-up event from:
 - LIN bus
 - Local wake-up through EN
- Integrated 45 kΩ LIN pull-up resistor
- Power up and power down glitch-free operation on LIN bus and RXD output
- Protection features:
 - ± 60 V LIN bus fault tolerant
 - Under voltage protection on V_{SUP}
 - TXD Dominant time out protection (DTO)
 - Thermal shutdown protection
 - Unpowered node or ground disconnection failsafe at system level.
- 3.5 mm × 5.5 mm VQFN package with improved automated optical inspection (AOI) capability

2 Applications

- Body electronics and lighting
- Hybrid electric vehicles and power train systems
- Infotainment and cluster
- Appliances

3 Description

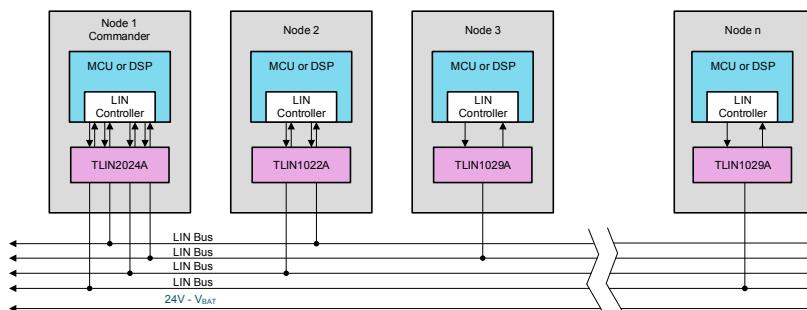
The TLIN2024A-Q1 device is a Quad Local Interconnect Network (LIN) physical layer transceiver, which integrates wake-up and protection features, compliant to LIN2.0, LIN2.1, LIN2.2, LIN2.2A and ISO/DIS 17987–4 standards. LIN is a single wire bidirectional bus typically used for low speed in-vehicle networks using data rates up to 20 kbps. The TLIN2024A-Q1 is designed to support 12-V and 24-V applications with wider operating voltage and additional bus-fault protection. The device has two separate dual LIN transceiver blocks. The $V_{SUP1/2}$ control separate dual transceiver blocks.

The TLIN2024A-Q1 receiver supports data rates up to 100 kbps for faster in-line programming. The device converts the LIN protocol data stream on the TXD input into a LIN bus signal using a current-limited wave-shaping driver which reduces electromagnetic emissions (EME). The receiver converts the data stream to logic level signals that are sent to the microprocessor through the open-drain RXD pin. Ultra-low current consumption is possible using the sleep mode which allows wake-up via LIN bus or EN pin.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)
TLIN2024A-Q1	VQFN (24)	3.50 mm × 5.50 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Simplified Schematic



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

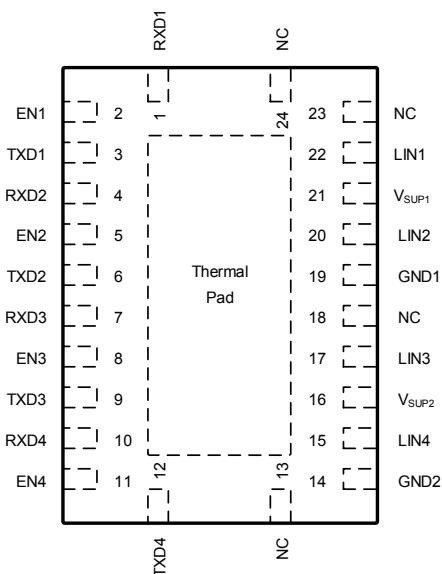
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
June 2022	*	Initial release

5 Description (Continued)

The TLIN2024A-Q1 integrates a resistor for LIN responder node applications, ESD protection, and fault protection which allow for a reduced number of external components in the applications. The device prevents back-feed current through LIN to the supply input in case of a ground shift or supply voltage disconnection. The device also includes undervoltage detection, temperature shutdown protection, and loss-of-ground protection.

6 Pin Configuration and Functions



**Figure 6-1. RGY Package, 24-Pin RGY (VQFN)
(Top View)**

Table 6-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
RXD1	1	O	Channel 1 RXD Output (open-drain) interface reporting state of LIN1 bus voltage
EN1	2	I	Channel 1 Enable Input
TXD1	3	I	Channel 1 TXD input interface to control state of LIN output
RXD2	4	O	Channel 2 RXD Output (open-drain) interface reporting state of LIN2 bus voltage
EN2	5	I	Channel 2 Enable Input
TXD2	6	I	Channel 2 TXD input interface to control state of LIN2 output
RXD3	7	O	Channel 3 RXD Output (open-drain) interface reporting state of LIN3 bus voltage
EN3	8	I	Channel 3 Enable Input
TXD3	9	I	Channel 3 TXD input interface to control state of LIN3 output
RXD4	10	O	Channel 4 RXD Output (open-drain) interface reporting state of LIN4 bus voltage
EN4	11	I	Channel 4 Enable Input
TXD4	12	I	Channel 4 TXD input interface to control state of LIN4 output
GND2	14	G	Ground pin for Channels 3 and 4
LIN4	15	I/O	Channel 4 LIN Bus single-wire transmitter and receiver
V _{SUP2}	16	Supply	Channels 3 and 4 Supply Voltage (connected to battery in series with external reverse blocking diode)
LIN3	17	I/O	Channel 3 LIN Bus single-wire transmitter and receiver
GND1	19	G	Ground pin for Channels 1 and 2
LIN2	20	I/O	Channel 2 LIN Bus single-wire transmitter and receiver
V _{SUP1}	21	Supply	Channels 1 and 2 Supply Voltage (connected to battery in series with external reverse blocking diode)
LIN1	22	I/O	Channel 1 LIN Bus single-wire transmitter and receiver
NC	13, 18, 23, 24	–	Not Connected
Thermal Pad		–	Can be connected to the PCB ground plane to improve thermal coupling

(1) I = Input, O = Output, I/O = Input or Output, G = Ground.

7 Specifications

7.1 Absolute Maximum Ratings

(1) (2)

Symbol	Parameter	MIN	MAX	UNIT
V_{SUP}	Supply voltage range (ISO/DIS 17987 Param 10)	-0.3	60	V
V_{LIN}	LIN bus input voltage (ISO/DIS 17987 Param 82)	-60	60	V
V_{LOGIC}	Logic pin voltage (RXD, TXD, EN)	-0.3	6	V
I_o	Logic pin output current		8	mA
T_J	Junction temperature range	-55	150	°C

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) All voltage values are with respect to ground terminal.

7.2 ESD Ratings

ESD Ratings			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM) classification level 3A: TXD, RXD, EN Pins, per AEC Q100-002 ⁽¹⁾	± 4000	V
		Human body model (HBM) classification level 3B: LIN and V_{SUP} Pin with respect to ground	± 8000	
		Charged device model (CDM) classification level C5, per AEC Q100-011	All pins ± 1500	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

7.3 ESD Ratings - IEC

ESD and Surge Protection Ratings			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge, LIN, V_{SUP} to GND ⁽¹⁾	IEC 62228-2 per ISO 10605 Contact discharge $R = 330 \Omega$, $C = 150 \text{ pF}$	± 8000	V

7.3 ESD Ratings - IEC (continued)

ESD and Surge Protection Ratings		VALUE	UNIT
V _{TRAN}	IEC 62228-2 per IEC 62215-3 12 V electrical systems Pulse 1	-100	V
	IEC 62215-3 24 V electrical systems ⁽²⁾ Pulse 1	-450	
	IEC 62228-2 per IEC 62215-3 12 V electrical systems 24 V electrical systems ⁽²⁾ Pulse 2	75	
	IEC 62228-2 per IEC 62215-3 12 V electrical systems Pulse 3a	-150	
	IEC 62215-3 24 V electrical systems ⁽²⁾ Pulse 3a	-225	
	IEC 62228-2 per IEC 62215-3 12 V electrical systems Pulse 3b	100	
	IEC 62215-3 24 V electrical systems ⁽²⁾ Pulse 3b	225	

(1) Results given here are specific to the IEC 62228-2 Integrated circuits – EMC evaluation of transceivers – Part 2: LIN transceivers. Testing performed by OEM approved independent 3rd party, EMC report available upon request.

(2) Verified during characterization.

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TLIN2024A	UNIT
		RGY (QFN)	
		24-PINS	
R _{θJA}	Junction-to-ambient thermal resistance	34.3	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	30.8	°C/W
R _{θJB}	Junction-to-board thermal resistance	13.3	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	0.5	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	13.3	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	2.8	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

7.5 Recommended Operating Conditions

parameters valid across $-40^{\circ}\text{C} \leq T_{\text{A}} \leq 125^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER - DEFINITION		MIN	NOM	MAX	UNIT
V _{SUP1/2}	Supply voltage	4	48	48	V
V _{LINx}	LIN Bus input voltage	0	48	48	V
V _{LOGIC}	Logic Pin Voltage (RXDx, TXDx, ENx)	0	5.25	5.25	V
T _A	Ambient temperature range	-40	125	125	°C
TSD	Thermal shutdown rising threshold	165			°C
TSD _(HYS)	Thermal shutdown hysteresis	15			°C

7.6 Electrical Characteristics

parameters valid across $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Supply						
$V_{\text{SUP1/2}}$	Operational supply voltage (ISO/DIS 17987 Param 10)	Device is operational beyond the LIN defined nominal supply voltage range; See Figure 8-1 and Figure 8-2	4	48	48	V
$V_{\text{SUP1/2}}$	Nominal supply voltage (ISO/DIS 17987 Param 10)	Normal and Standby Modes: ramp V_{SUP} while LIN signal is a 10 kHz square wave with 50 % duty cycle and 36V swing; See Figure 8-1 and Figure 8-2	4	48	48	V
		Sleep Mode	4	48	48	V
UV_{SUP}	Under voltage V_{SUP} threshold		2.9	3.85	3.85	V
UV_{HYS}	Delta hysteresis voltage for V_{SUP} under voltage threshold			0.2	0.2	V
I_{SUP}	Supply current ⁽⁶⁾	Normal Mode: EN = High, bus dominant: total bus load where $R_{\text{LIN}} > 500 \Omega$ and $C_{\text{LIN}} < 10 \text{ nF}$		1.2	8.5	mA
		Standby Mode: EN = Low, bus dominant: total bus load where $R_{\text{LIN}} > 500 \Omega$ and $C_{\text{LIN}} < 10 \text{ nF}$		1.1	3.75	mA
I_{SUP}	Supply current ⁽⁶⁾	Normal Mode: EN = High, Bus Recessive: LIN = V_{SUP}		670	1600	μA
		Standby Mode: EN = Low, Bus Recessive LIN = V_{SUP}		20	40	μA
		Sleep Mode: $4.0 \text{ V} < V_{\text{SUP}} < 14 \text{ V}$, LIN = V_{SUP} , EN = 0 V, TXD and RXD Floating		10	20	μA
		Sleep Mode: $14 \text{ V} < V_{\text{SUP}} < 36 \text{ V}$, LIN = V_{SUP} , EN = 0 V, TXD and RXD floating			30	μA
RDX_x OUTPUT PIN (OPEN DRAIN)						
V_{OL}	Output Low voltage	Based upon External pull up to V_{CC} ⁽⁴⁾			0.6	V
I_{OL}	Low level output current, open drain	LIN = 0 V, RXD = 0.4 V	1.5			mA
I_{ILG}	Leakage current, high-level	LIN = V_{SUP} , RXD = 5 V	-5	0	5	μA
TXD_x INPUT PIN						
V_{IL}	Low level input voltage		-0.3	0.8	0.8	V
V_{IH}	High level input voltage		2	5.25	5.25	V
V_{HYS}	Input threshold voltage, normal modes & selective wake modes			50	500	mV
I_{ILG}	Low level input leakage current	TXD = Low	-5	0	5	μA
R_{TXD}	Internal pull-down resistor value		125	350	800	k Ω
EN_x INPUT PIN						
V_{IL}	Low level input voltage		-0.3	0.8	0.8	V
V_{IH}	High level input voltage		2	5.25	5.25	V
V_{HYS}	Hysteresis voltage	By design and characterization		50	500	mV
I_{ILG}	Low level input current	EN = Low	-5	0	5	μA
R_{EN}	Internal Pulldown resistor		125	350	800	k Ω
LIN_x PIN						
V_{OH}	LIN recessive high-level output voltage ⁽³⁾	TXD = high, $I_{\text{O}} = 0 \text{ mA}$, $7 \text{ V} \leq V_{\text{SUP}} \leq 48 \text{ V}$		0.85		V_{SUP}
V_{OH}	LIN recessive high-level output voltage ^{(1) (2)}	TXD = high, $I_{\text{O}} = 0 \text{ mA}$, $7 \text{ V} \leq V_{\text{SUP}} \leq 18 \text{ V}$		0.8		V_{SUP}
V_{OH}	LIN recessive high-level output voltage ⁽³⁾	TXD = high, $I_{\text{O}} = 0 \text{ mA}$, $4 \text{ V} \leq V_{\text{SUP}} < 7 \text{ V}$		3		V

7.6 Electrical Characteristics (continued)

parameters valid across $-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V_{OL}	LIN dominant low-level output voltage ⁽³⁾	TXD = low, $7\text{ V} \leq V_{SUP} \leq 48\text{ V}$		0.2	V_{SUP}	
V_{OL}	LIN dominant low-level output voltage ⁽¹⁾ ⁽²⁾	TXD = low, $7\text{ V} \leq V_{SUP} \leq 18\text{ V}$		0.2	V_{SUP}	
V_{OL}	LIN dominant low-level output voltage ⁽³⁾	TXD = low, $4\text{ V} \leq V_{SUP} < 7\text{ V}$		1.2	V	
$V_{SUP_NON_OP}$	V_{SUP} where impact of recessive LIN bus < 5% (ISO/DIS 17987 Param 11)	TXD & RXD open, LIN = 4 V to 58 V	-0.3	58	V	
I_{BUS_LIM}	Limiting current (ISO/DIS 17987 Param 57)	TXD = 0 V, $V_{LIN} = 48\text{ V}$, $R_{MEAS} = 440\text{ }\Omega$, $V_{SUP} = 48\text{ V}$, $V_{BUSdom} < 4.518\text{ V}$	75	120	300	mA
$I_{BUS_PAS_dom}$	Receiver leakage current, dominant (ISO/DIS 17987 Param 13)	LIN = 0 V, $V_{SUP} = 24\text{ V}$ Driver off/recessive; See Figure 8-6	-2		mA	
$I_{BUS_PAS_rec1}$	Receiver leakage current, recessive (ISO/DIS 17987 Param 14)	LIN > V_{SUP} , $8\text{ V} \leq V_{SUP} \leq 48\text{ V}$, Driver off; See Figure 8-7		20	μA	
$I_{BUS_PAS_rec2}$	Receiver leakage current, recessive (ISO/DIS 17987 Param 14)	LIN = V_{SUP} , Driver off; See Figure 8-7	-5	5	μA	
$I_{BUS_NO_GND}$	Leakage current, loss of ground (ISO/DIS 17987 Param 60)	GND = V_{SUP} , $0\text{ V} \leq V_{LIN} < 36\text{ V}$, $V_{SUP} = 24\text{ V}$; Figure 8-8	-2	2	mA	
$I_{leak\ gnd(dom)}$	Leakage current, loss of ground ⁽⁵⁾	$V_{SUP} = 8\text{ V}$, GND = open, $V_{SUP} = 18\text{ V}$, GND = open $R_{Commander} = 1\text{ k}\Omega$, $C_L = 1\text{ nF}$ $R_{Responder} = 20\text{ k}\Omega$, $C_L = 1\text{ nF}$ LIN = dominant	-1	1	mA	
$I_{leak\ gnd(rec)}$	Leakage current, loss of ground ⁽⁵⁾	$V_{SUP} = 8\text{ V}$, GND = open, $V_{SUP} = 18\text{ V}$, GND = open $R_{Commander} = 1\text{ k}\Omega$, $C_L = 1\text{ nF}$ $R_{Responder} = 20\text{ k}\Omega$, $C_L = 1\text{ nF}$ LIN = recessive	-100	100	μA	
$I_{BUS_NO_BAT}$	Leakage current, loss of supply (ISO/DIS 17987 Param 61)	$0\text{ V} \leq V_{LIN} \leq 48\text{ V}$, $V_{SUP} = \text{GND}$; See: Figure 8-9		5	μA	
V_{BUSdom}	Low level input voltage (ISO/DIS 17987 Param 62) ⁽³⁾	LIN dominant (including LIN dominant for wake-up); See Figure 8-4 and Figure 8-3		0.4	V_{SUP}	
V_{BUSrec}	High level input voltage (ISO/DIS 17987 Param 63) ⁽³⁾	LIN recessive; See Figure 8-4 and Figure 8-3	0.6		V_{SUP}	
V_{IH}	LIN recessive high-level input voltage ⁽¹⁾ ⁽²⁾	$7\text{ V} \leq V_{SUP} \leq 18\text{ V}$	0.47	0.6	V_{SUP}	
V_{IL}	LIN dominant low-level input voltage ⁽¹⁾ ⁽²⁾	$7\text{ V} \leq V_{SUP} \leq 18\text{ V}$	0.4	0.53	V_{SUP}	
V_{BUS_CNT}	Receiver center threshold (ISO/DIS 17987 Param 64)	$V_{BUS_CNT} = (V_{BUSdom} + V_{BUSrec})/2$ See Figure 8-4 and Figure 8-3	0.475	0.5	0.525	V_{SUP}
V_{HYS}	Hysteresis voltage (ISO/DIS 17987 Param 65)	$V_{HYS} = (V_{BUSrec} - V_{BUSdom})$ See Figure 8-4 and Figure 8-3		0.175	V_{SUP}	
V_{HYS}	Hysteresis voltage (SAE J2602)	$V_{HYS} = V_{IH} - V_{IL}$ See Figure 8-4 and Figure 8-3	0.07	0.175	V_{SUP}	
V_{SERIAL_DIODE}	Serial diode LIN termination pullup path	$I_{SERIAL_DIODE} = 10\text{ }\mu\text{A}$	0.4	0.7	1	V
R_{PU}	Pullup resistor to V_{SUP} (ISO/DIS 17987 Param 26)	Normal and Standby modes	20	45	60	$\text{k}\Omega$
I_{RSLEEP}	Pullup current source to V_{SUP}	Sleep mode, $V_{SUP} = 27\text{ V}$, LIN = GND	-20	-2	μA	
C_{LINPIN}	Capacitance of the LIN pin	$V_{SUP} = 14\text{ V}$		25	pF	

(1) SAE 2602 commander node load conditions: $5.5\text{ nF}/4\text{ k}\Omega$ and $899\text{ pF}/20\text{ k}\Omega$

(2) SAE 2602 responder node load conditions: $5.5\text{ nF}/875\text{ }\Omega$ and $899\text{ pF}/900\text{ }\Omega$

(3) ISO 17987 bus load conditions (C_{LINBUS} , R_{LINBUS}) include $1\text{ nF}/1\text{ k}\Omega$; $6.8\text{ nF}/660\text{ }\Omega$; $10\text{ nF}/500\text{ }\Omega$.

(4) RXD uses open drain output structure therefore V_{OL} level is based upon microcontroller supply voltage V_{CC} .

(5) $I_{leak\ gnd} = (V_{BAT} - V_{LIN})/R_{Load}$

(6) Values are for each V_{SUP} pin

7.7 Duty Cycle Characteristics

parameters valid across $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
D1 _{12V}	Duty Cycle 1 (ISO/DIS 17987 Param 27) ⁽³⁾	$TH_{REC(MAX)} = 0.744 \times V_{SUP}$, $TH_{DOM(MAX)} = 0.581 \times V_{SUP}$, $V_{SUP} = 7 \text{ V to } 18 \text{ V}$, $t_{BIT} = 50 \mu\text{s}$ (20 kbps), $D1 = t_{BUS_rec(min)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)	0.396			
D1 _{12V}	Duty Cycle 1 ^{(3) (4)}	$TH_{REC(MAX)} = 0.625 \times V_{SUP}$, $TH_{DOM(MAX)} = 0.581 \times V_{SUP}$, $V_{SUP} = 4 \text{ V to } 7 \text{ V}$, $t_{BIT} = 50 \mu\text{s}$ (20 kbps), $D1 = t_{BUS_rec(min)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)	0.396			
D1	Duty Cycle 1 ^{(1) (2) (4)}	$TH_{REC(MAX)} = 0.744 \times V_{SUP}$, $TH_{DOM(MAX)} = 0.581 \times V_{SUP}$, $V_{SUP} = 7 \text{ V to } 18 \text{ V}$, $t_{BIT} = 52 \mu\text{s}$ $D1 = t_{BUS_rec(min)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)	0.396			
D2 _{12V}	Duty Cycle 2 (ISO/DIS 17987 Param 28) ⁽³⁾	$TH_{REC(MIN)} = 0.422 \times V_{SUP}$, $TH_{DOM(MIN)} = 0.284 \times V_{SUP}$, $V_{SUP} = 7 \text{ V to } 18 \text{ V}$, $t_{BIT} = 50 \mu\text{s}$ (20 kbps), $D2 = t_{BUS_rec(MAX)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)		0.581		
D2 _{12V}	Duty Cycle 2 ^{(3) (4)}	$TH_{REC(MIN)} = 0.546 \times V_{SUP}$, $TH_{DOM(MIN)} = 0.4 \times V_{SUP}$, $V_{SUP} = 4 \text{ V to } 7 \text{ V}$, $t_{BIT} = 50 \mu\text{s}$ (20 kbps), $D2 = t_{BUS_rec(MAX)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)		0.581		
D2	Duty Cycle 2 ^{(1) (2) (4)}	$TH_{REC(MIN)} = 0.422 \times V_{SUP}$, $TH_{DOM(MIN)} = 0.284 \times V_{SUP}$, $V_{SUP} = 7 \text{ V to } 18 \text{ V}$, $t_{BIT} = 52 \mu\text{s}$ $D2 = t_{BUS_rec(MAX)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)		0.581		
D3 _{12V}	Duty Cycle 3 (ISO/DIS 17987 Param 29) ⁽³⁾	$TH_{REC(MAX)} = 0.778 \times V_{SUP}$, $TH_{DOM(MAX)} = 0.616 \times V_{SUP}$, $V_{SUP} = 7 \text{ V to } 18 \text{ V}$, $t_{BIT} = 96 \mu\text{s}$ (10.4 kbps), $D3 = t_{BUS_rec(min)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)	0.417			
D3 _{12V}	Duty Cycle 3 ^{(3) (4)}	$TH_{REC(MAX)} = 0.645 \times V_{SUP}$, $TH_{DOM(MAX)} = 0.616 \times V_{SUP}$, $V_{SUP} = 4 \text{ V to } 7 \text{ V}$, $t_{BIT} = 96 \mu\text{s}$ (10.4 kbps), $D3 = t_{BUS_rec(min)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)	0.417			
D3	Duty Cycle 3 ^{(1) (2) (4)}	$TH_{REC(MAX)} = 0.778 \times V_{SUP}$, $TH_{DOM(MAX)} = 0.616 \times V_{SUP}$, $V_{SUP} = 7 \text{ V to } 18 \text{ V}$, $t_{BIT} = 96 \mu\text{s}$ $D3 = t_{BUS_rec(min)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)	0.417			
D4 _{12V}	Duty Cycle 4 (ISO/DIS 17987 Param 30) ⁽³⁾	$TH_{REC(MIN)} = 0.389 \times V_{SUP}$, $TH_{DOM(MIN)} = 0.251 \times V_{SUP}$, $V_{SUP} = 7 \text{ V to } 18 \text{ V}$, $t_{BIT} = 96 \mu\text{s}$ (10.4 kbps), $D4 = t_{BUS_rec(MAX)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)		0.59		
D4 _{12V}	Duty Cycle 4 ^{(3) (4)}	$TH_{REC(MIN)} = 0.422 \times V_{SUP}$, $TH_{DOM(MIN)} = 0.284 \times V_{SUP}$, $V_{SUP} = 4 \text{ V to } 7 \text{ V}$, $t_{BIT} = 96 \mu\text{s}$ (10.4 kbps), $D4 = t_{BUS_rec(MAX)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)		0.59		
D4	Duty Cycle 4 ^{(1) (2) (4)}	$TH_{REC(MIN)} = 0.389 \times V_{SUP}$, $TH_{DOM(MIN)} = 0.251 \times V_{SUP}$, $V_{SUP} = 7 \text{ V to } 18 \text{ V}$, $t_{BIT} = 96 \mu\text{s}$ $D4 = t_{BUS_rec(MAX)} / (2 \times t_{BIT})$ (See Figure 8-10, Figure 8-11)		0.59		

7.7 Duty Cycle Characteristics (continued)

parameters valid across $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
D1 _{24V}	$\text{TH}_{\text{REC}(\text{MAX})} = 0.710 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.544 \times V_{\text{SUP}}$, $V_{\text{SUP}} = 15 \text{ V to } 36 \text{ V}$, $t_{\text{BIT}} = 50 \mu\text{s}$ (20 kbps), D1 = $t_{\text{BUS_rec}(\text{min})}/(2 \times t_{\text{BIT}})$ (See Figure 8-10, Figure 8-11)	0.33			
D2 _{24V}	$\text{TH}_{\text{REC}(\text{MIN})} = 0.446 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MIN})} = 0.302 \times V_{\text{SUP}}$, $V_{\text{SUP}} = 15.6 \text{ V to } 36 \text{ V}$, $t_{\text{BIT}} = 50 \mu\text{s}$ (20 kbps), D2 = $t_{\text{BUS_rec}(\text{MAX})}/(2 \times t_{\text{BIT}})$ (See Figure 8-10, Figure 8-11)		0.642		
D3 _{24V}	$\text{TH}_{\text{REC}(\text{MAX})} = 0.744 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.581 \times V_{\text{SUP}}$, $V_{\text{SUP}} = 7 \text{ V to } 36 \text{ V}$, $t_{\text{BIT}} = 96 \mu\text{s}$ (10.4 kbps), D3 = $t_{\text{BUS_rec}(\text{min})}/(2 \times t_{\text{BIT}})$ (See Figure 8-10, Figure 8-11)	0.386			
D4 _{24V}	$\text{TH}_{\text{REC}(\text{MIN})} = 0.422 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MIN})} = 0.284 \times V_{\text{SUP}}$, $V_{\text{SUP}} = 7.6 \text{ V to } 36 \text{ V}$, $t_{\text{BIT}} = 96 \mu\text{s}$ (10.4 kbps), D4 = $t_{\text{BUS_rec}(\text{MAX})}/(2 \times t_{\text{BIT}})$ (See Figure 8-10, Figure 8-11)		0.591		
D1 _{LB}	$\text{TH}_{\text{REC}(\text{MAX})} = 0.665 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.499 \times V_{\text{SUP}}$, $V_{\text{SUP}} = 5.5 \text{ V to } 7 \text{ V}$, $t_{\text{BIT}} = 52 \mu\text{s}$	0.396			
D2 _{LB}	$\text{TH}_{\text{REC}(\text{MAX})} = 0.496 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.361 \times V_{\text{SUP}}$, $V_{\text{SUP}} = 6.1 \text{ V to } 7 \text{ V}$, $t_{\text{BIT}} = 52 \mu\text{s}$		0.581		
D3 _{LB}	$\text{TH}_{\text{REC}(\text{MAX})} = 0.665 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.499 \times V_{\text{SUP}}$, $V_{\text{SUP}} = 5.5 \text{ V to } 7 \text{ V}$, $t_{\text{BIT}} = 96 \mu\text{s}$	0.396			
D4 _{LB}	$\text{TH}_{\text{REC}(\text{MAX})} = 0.496 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.361 \times V_{\text{SUP}}$, $V_{\text{SUP}} = 6.1 \text{ V to } 7 \text{ V}$, $t_{\text{BIT}} = 96 \mu\text{s}$		0.581		
Tr-d max	Transmitter propagation delay timings for the duty cycle (1) (2) (4) Recessive to dominant	$\text{TH}_{\text{REC}(\text{MAX})} = 0.744 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.581 \times V_{\text{SUP}}$, $7 \text{ V} \leq V_{\text{SUP}} \leq 18 \text{ V}$, $t_{\text{BIT}} = 52 \mu\text{s}$ $t_{\text{REC}(\text{MAX})_D1} - t_{\text{DOM}(\text{MIN})_D1}$		10.8	μs
Td-r max	Transmitter propagation delay timings for the duty cycle (1) (2) (4) Dominant to recessive	$\text{TH}_{\text{REC}(\text{MAX})} = 0.422 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.284 \times V_{\text{SUP}}$, $7 \text{ V} \leq V_{\text{SUP}} \leq 18 \text{ V}$, $t_{\text{BIT}} = 52 \mu\text{s}$ $t_{\text{DOM}(\text{MAX})_D2} - t_{\text{REC}(\text{MIN})_D2}$		8.4	μs
Tr-d max	Transmitter propagation delay timings for the duty cycle (1) (2) (4) Recessive to dominant	$\text{TH}_{\text{REC}(\text{MAX})} = 0.778 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.616 \times V_{\text{SUP}}$, $7 \text{ V} \leq V_{\text{SUP}} \leq 18 \text{ V}$, $t_{\text{BIT}} = 96 \mu\text{s}$ $t_{\text{REC}(\text{MAX})_D3} - t_{\text{DOM}(\text{MIN})_D3}$		15.9	μs
Td-r max	Transmitter propagation delay timings for the duty cycle (1) (2) (4) Dominant to recessive	$\text{TH}_{\text{REC}(\text{MIN})} = 0.389 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MIN})} = 0.251 \times V_{\text{SUP}}$, $7 \text{ V} \leq V_{\text{SUP}} \leq 18 \text{ V}$, $t_{\text{BIT}} = 96 \mu\text{s}$ $t_{\text{DOM}(\text{MAX})_D4} - t_{\text{REC}(\text{MIN})_D4}$		17.28	μs
Tr-d max_low	Low battery transmitter propagation delay timings for the duty cycle (1) (2) (4) Recessive to dominant	$\text{TH}_{\text{REC}(\text{MAX})} = 0.665 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.499 \times V_{\text{SUP}}$, $5.5 \text{ V} \leq V_{\text{SUP}} \leq 7 \text{ V}$, $t_{\text{BIT}} = 52 \mu\text{s}$ $t_{\text{REC}(\text{MAX})_low} - t_{\text{DOM}(\text{MIN})_low}$		10.8	μs
Td-r max_low	Low battery transmitter propagation delay timings for the duty cycle (1) (2) (4) Dominant to recessive	$\text{TH}_{\text{REC}(\text{MAX})} = 0.496 \times V_{\text{SUP}}$, $\text{TH}_{\text{DOM}(\text{MAX})} = 0.361 \times V_{\text{SUP}}$, $6.1 \text{ V} \leq V_{\text{SUP}} \leq 7 \text{ V}$, $t_{\text{BIT}} = 52 \mu\text{s}$ $t_{\text{DOM}(\text{MAX})_low} - t_{\text{REC}(\text{MIN})_low}$		8.4	μs

(1) SAE 2602 commander node load conditions: 5.5 nF/4 kΩ and 899 pF/20 kΩ

(2) SAE 2602 responder node load conditions: 5.5 nF/875 Ω and 899 pF/900 Ω

(3) ISO 17987 bus load conditions (C_{LINBUS} , R_{LINBUS}) include 1 nF/1 kΩ; 6.8 nF/660 Ω; 10 nF/500 Ω.
(4) Specified by design

7.8 Switching Characteristics

parameters valid across $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ (unless otherwise noted)

SYMBOL	DESCRIPTION	TEST CONDITIONS	MIN	NOM	MAX	UNIT
t_{rx_pdr}	Receiver rising propagation delay time (ISO/DIS 17987 Param 31)	$R_{RXD} = 2.4 \text{ k}\Omega$, $C_{RXD} = 20 \text{ pF}$; (See Figure 8-12 and Figure 8-13)	6	μs	6	μs
t_{rx_pdf}	Receiver falling propagation delay time (ISO/DIS 17987 Param 31)					
t_{rs_sym}	Symmetry of receiver propagation delay time	Rising edge with respect to falling edge, ($tr_{sym} = tr_{pdf} - tr_{pdr}$), $R_{RXD} = 2.4 \text{ k}\Omega$, $C_{RXD} = 20 \text{ pF}$; (See Figure 8-12 and Figure 8-13)	-2	2	2	μs
t_{LINBUS}	LIN wake-up time (Minimum dominant time on LIN bus for wake-up)	See Figure 8-16 , Figure 9-2 , and Figure 9-3	25	100	150	μs
t_{CLEAR}	Time to clear false wake-up prevention logic if LIN bus had a bus stuck dominant fault (recessive time on LIN bus to clear bus stuck dominant fault)	See Figure 9-3	8	17	50	μs
t_{DST}	Dominant state time out		20	34	80	ms
t_{MODE_CHANGE}	Mode change delay time	Time to change from standby mode to normal mode or normal mode to sleep mode through EN pin; See Figure 8-14 and Figure 9-4	2	15	15	μs
t_{NOMINT}	Normal mode initialization time	Time for normal mode to initialize and data on RXD pin to be valid; See Figure 8-14			35	μs
t_{PWR}	Power up time	Upon power up time it takes for valid data on RXD			1.5	ms

8 Parameter Measurement Information

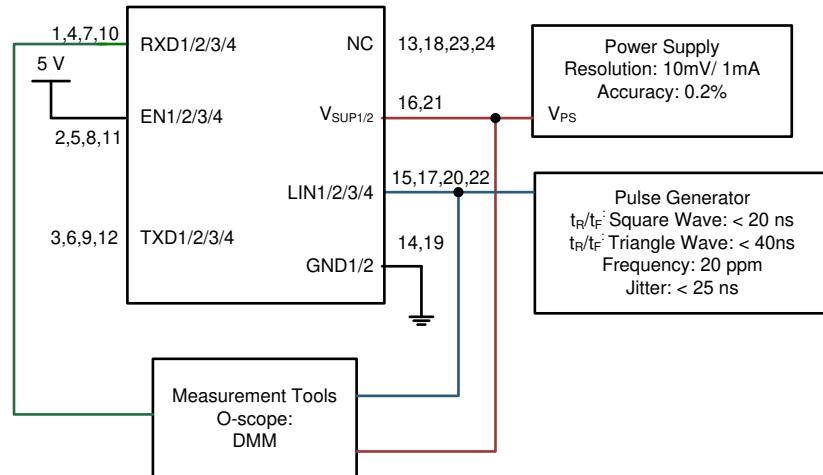


Figure 8-1. Test System: Operating Voltage Range with RX and TX Access

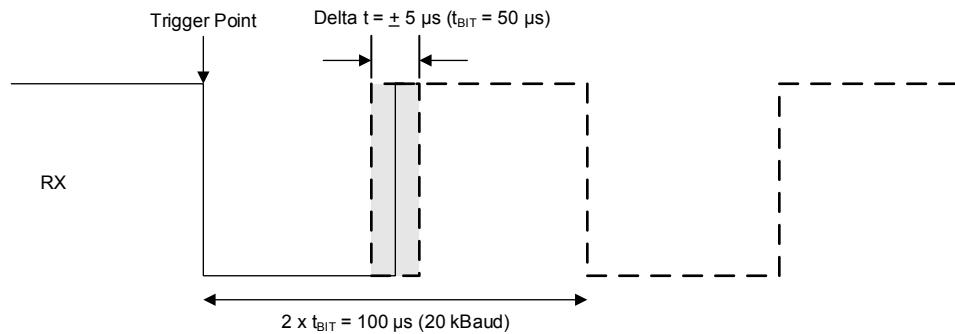


Figure 8-2. RX Response: Operating Voltage Range

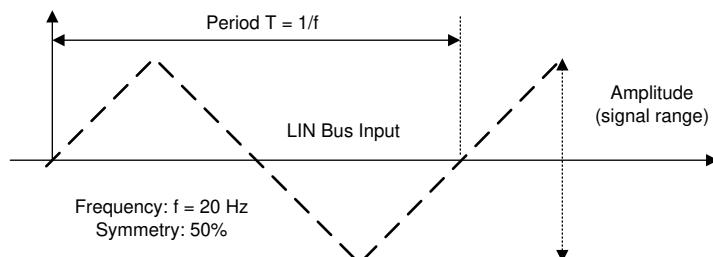


Figure 8-3. LIN Bus Input Signal

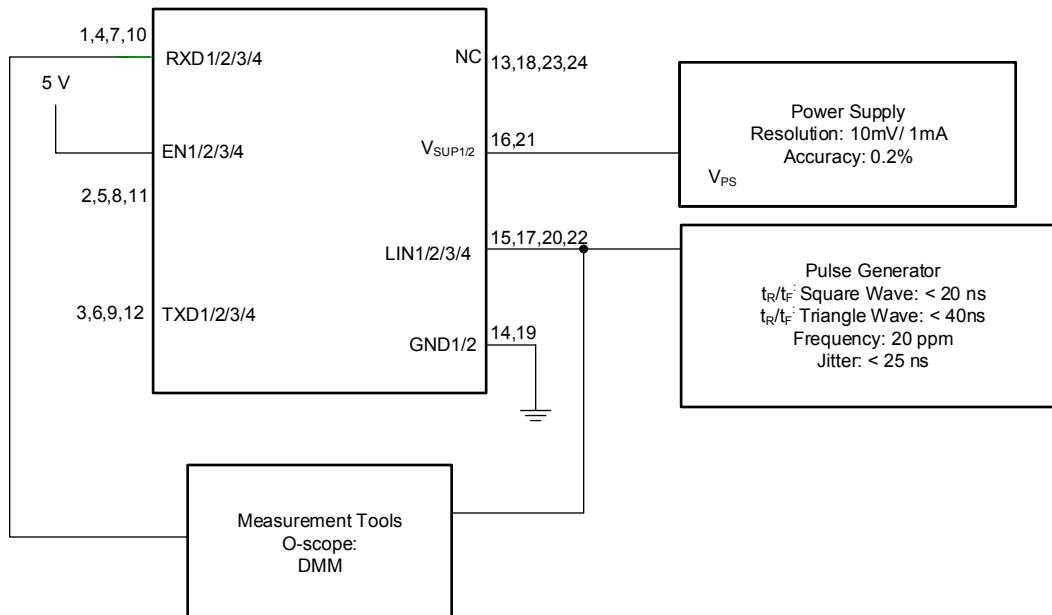


Figure 8-4. LIN Receiver Test with RX Access

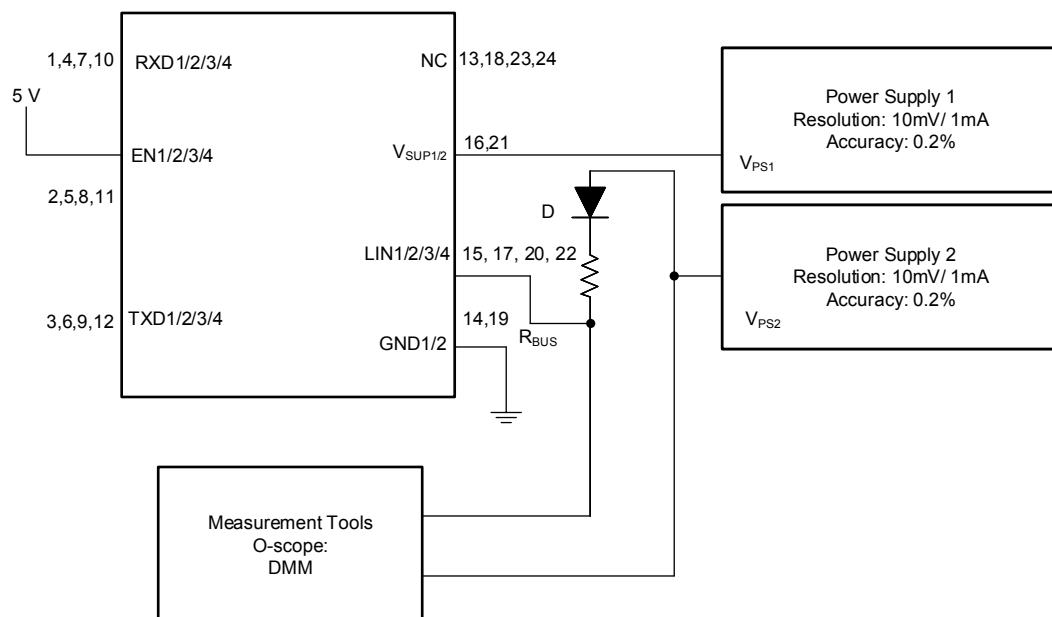


Figure 8-5. $V_{SUP_NON_OP}$

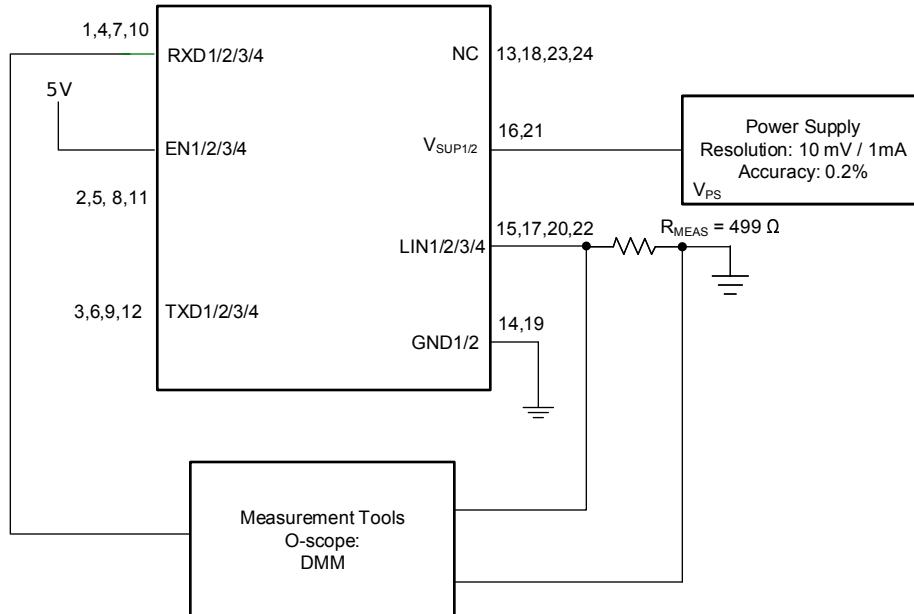


Figure 8-6. Test Circuit for $I_{BUS_PAS_dom}$; $TXD = \text{Recessive State}$ $V_{BUS} = 0 \text{ V}$

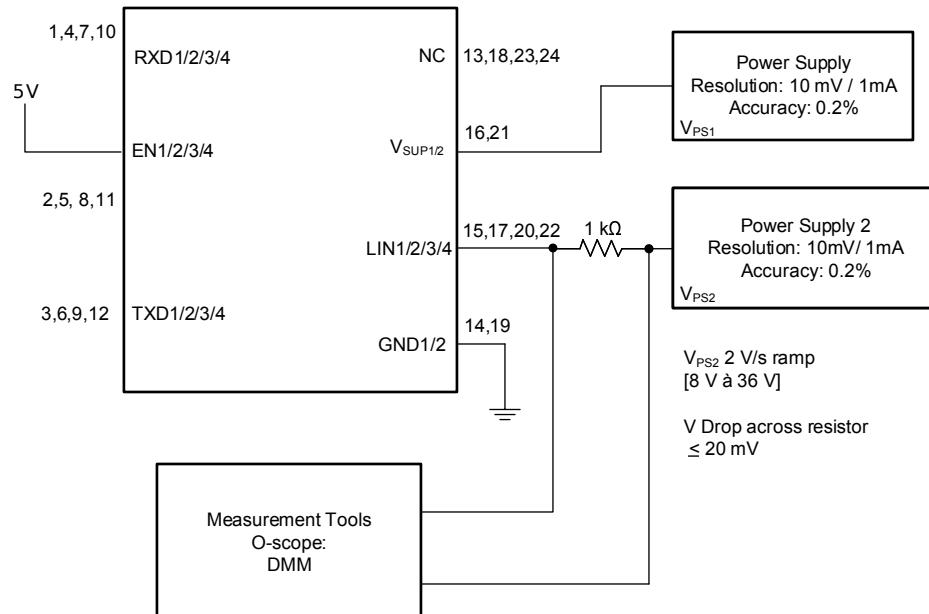


Figure 8-7. Test Circuit for $I_{BUS_PAS_rec}$

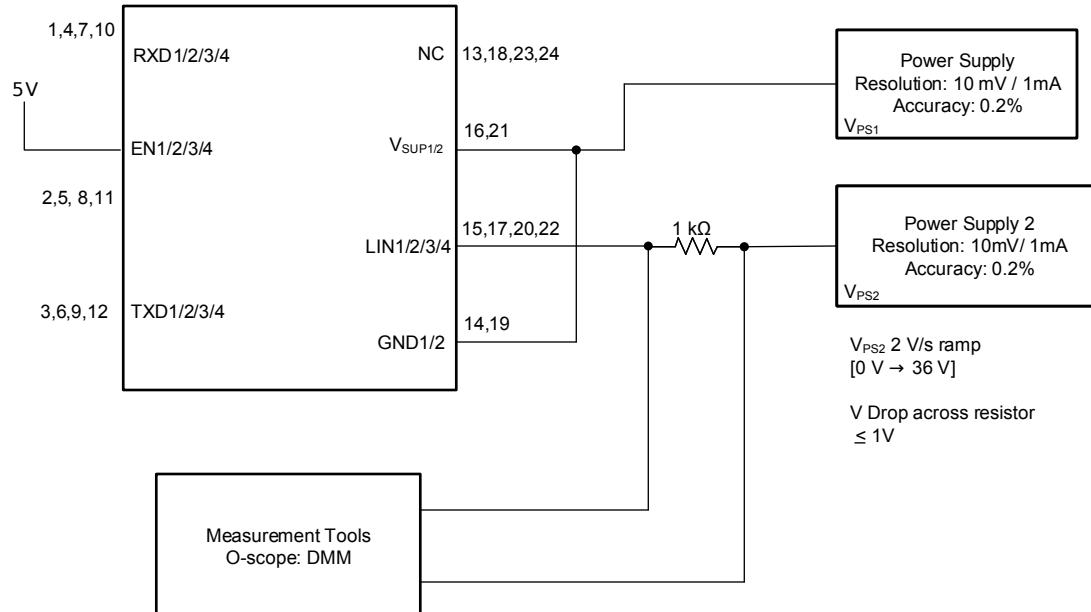


Figure 8-8. Test Circuit for $I_{BUS_NO_GND}$ Loss of GND

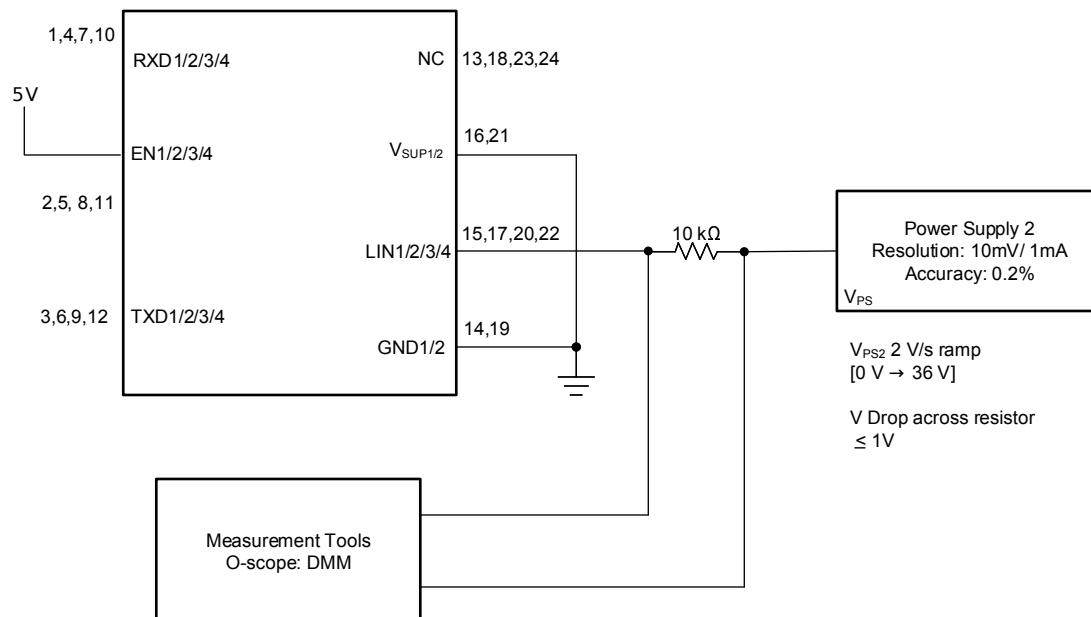


Figure 8-9. Test Circuit for $I_{BUS_NO_BAT}$ Loss of Battery

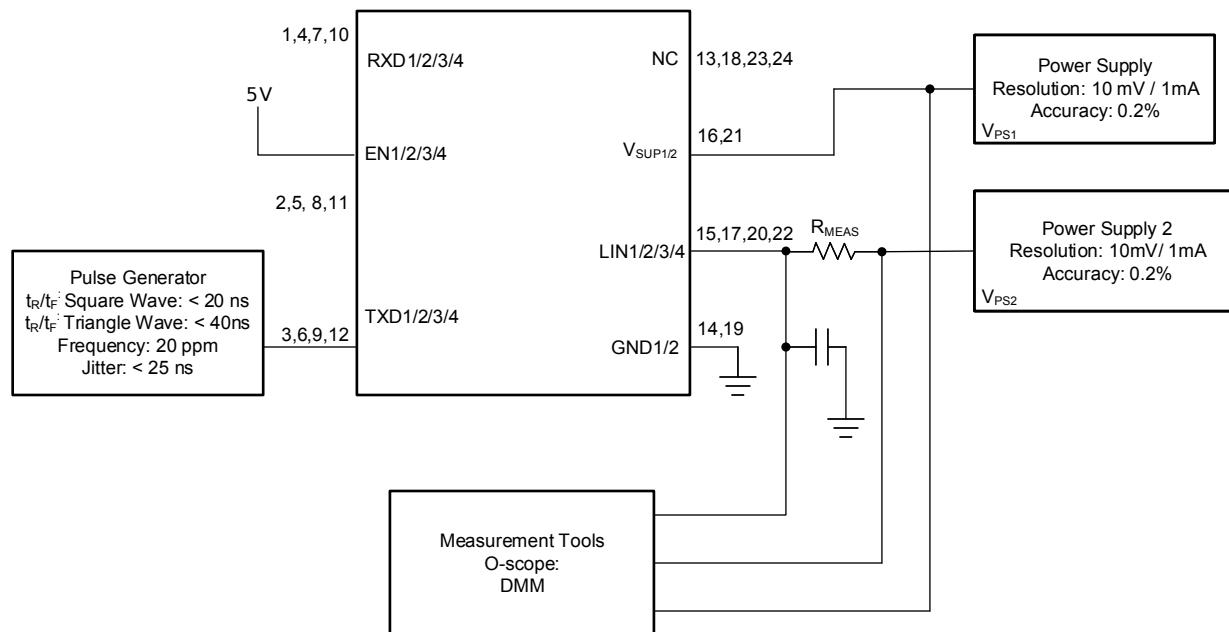


Figure 8-10. Test Circuit Slope Control and Duty Cycle

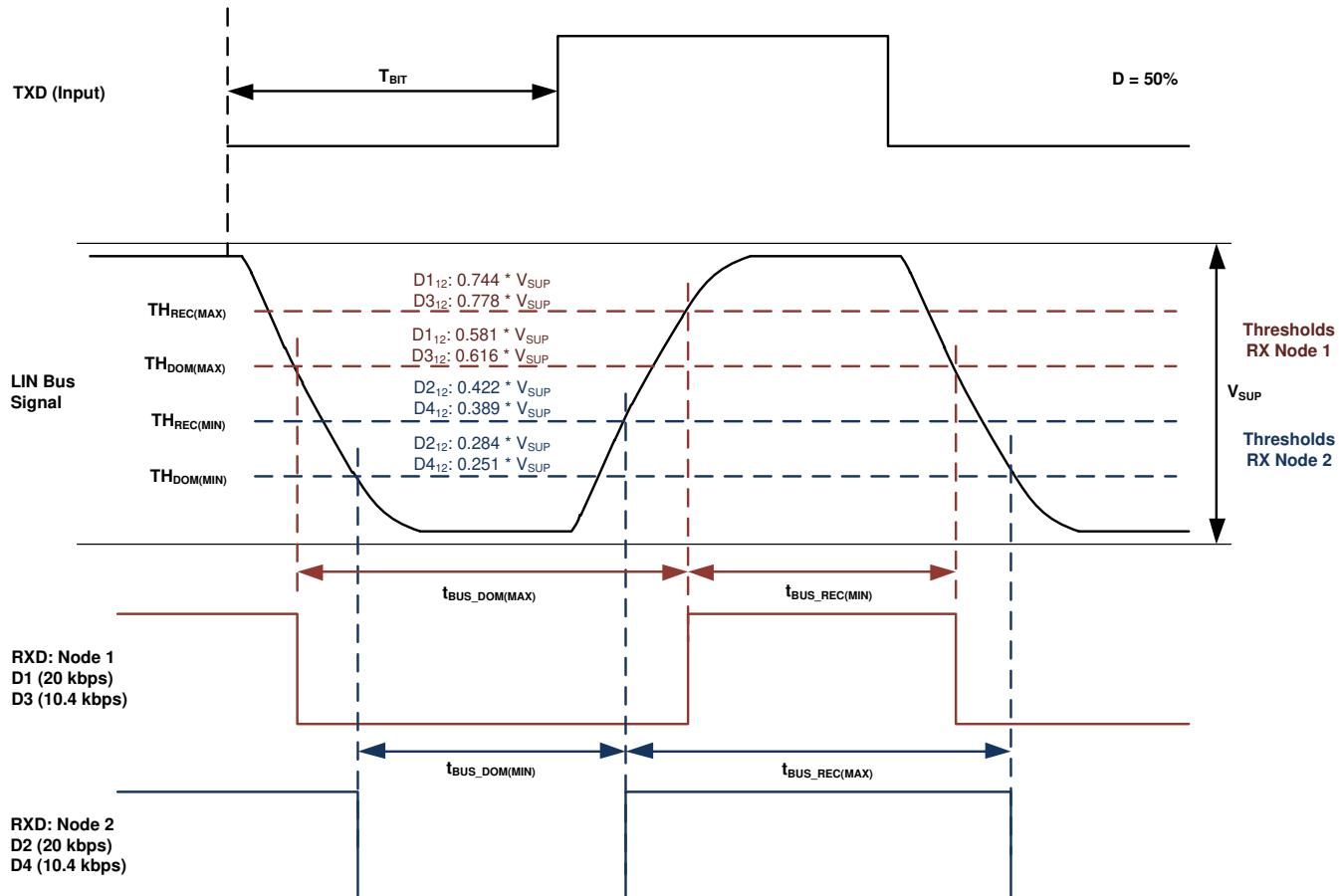


Figure 8-11. Definition of Bus Timing Parameters

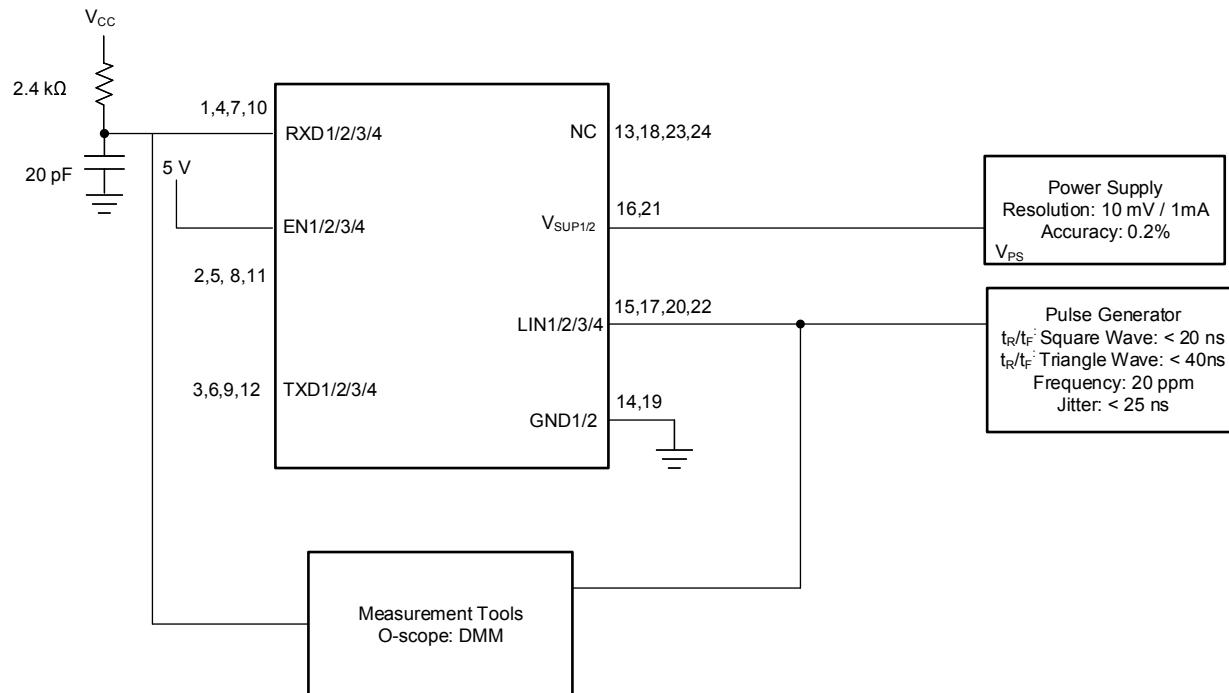


Figure 8-12. Propagation Delay Test Circuit

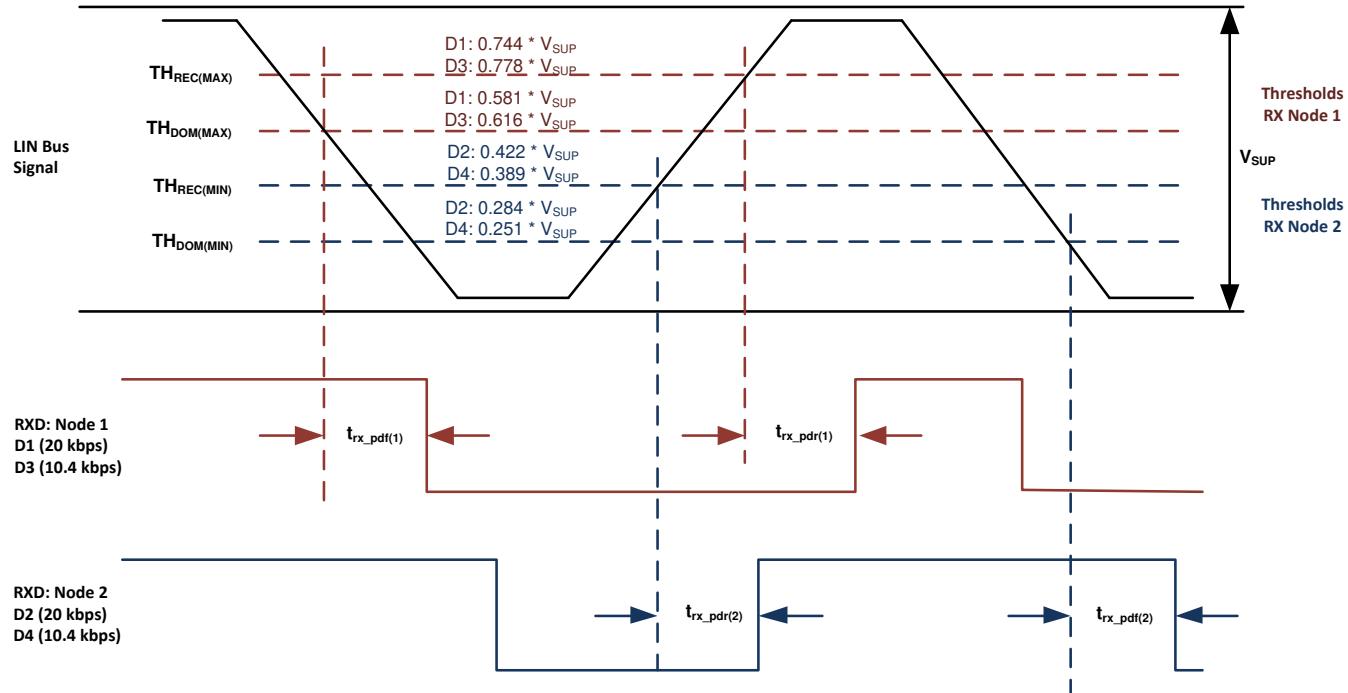


Figure 8-13. Propagation Delay

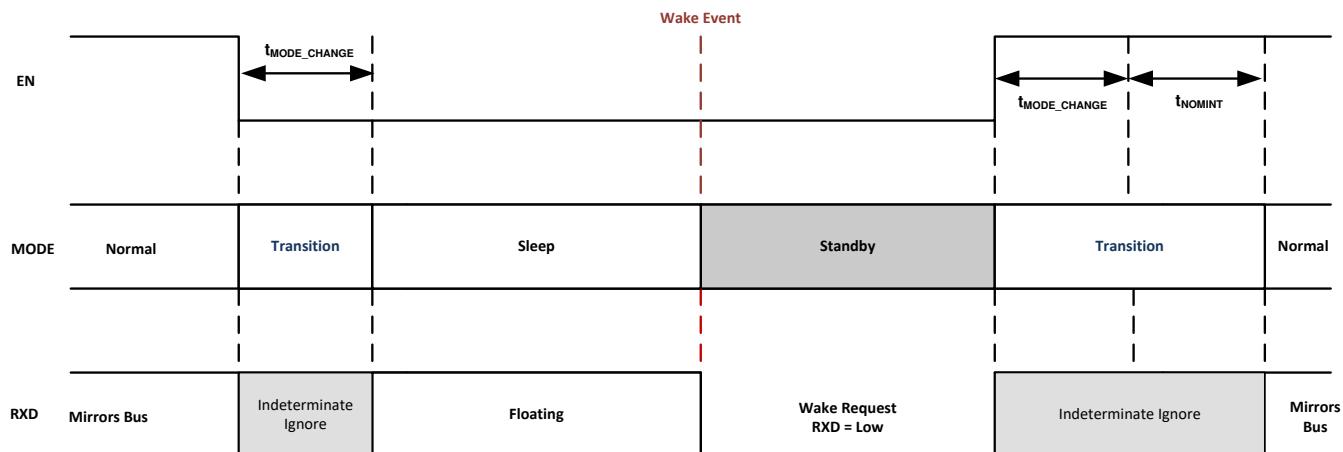


Figure 8-14. Mode Transitions

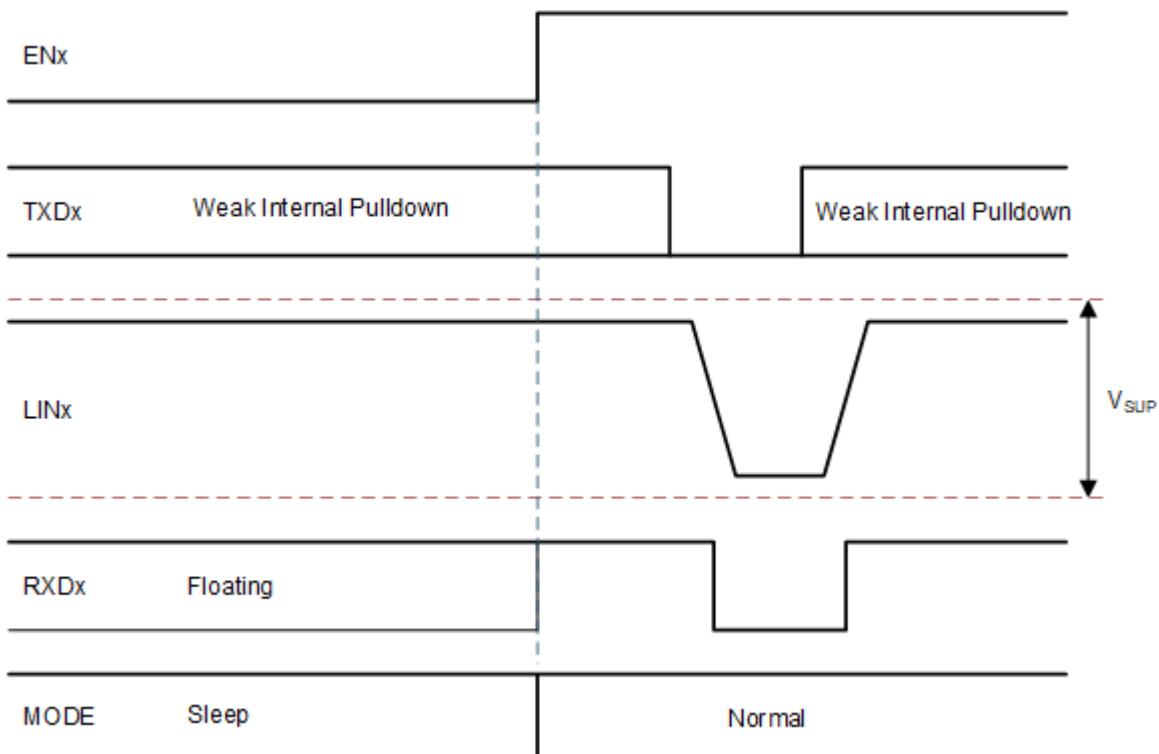


Figure 8-15. Wake-Up Through EN

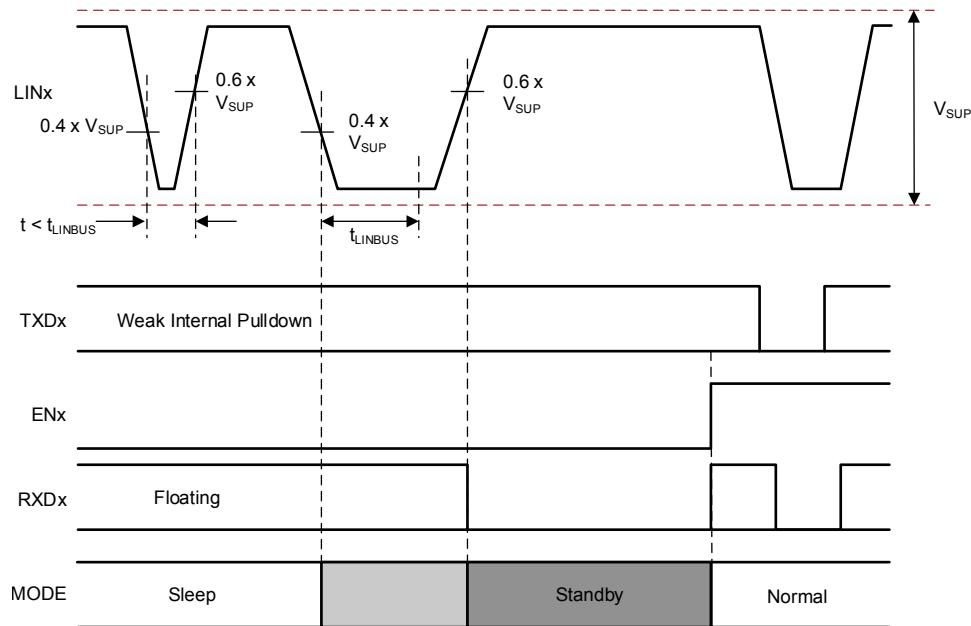


Figure 8-16. Wake-Up Through LIN

9 Detailed Description

9.1 Overview

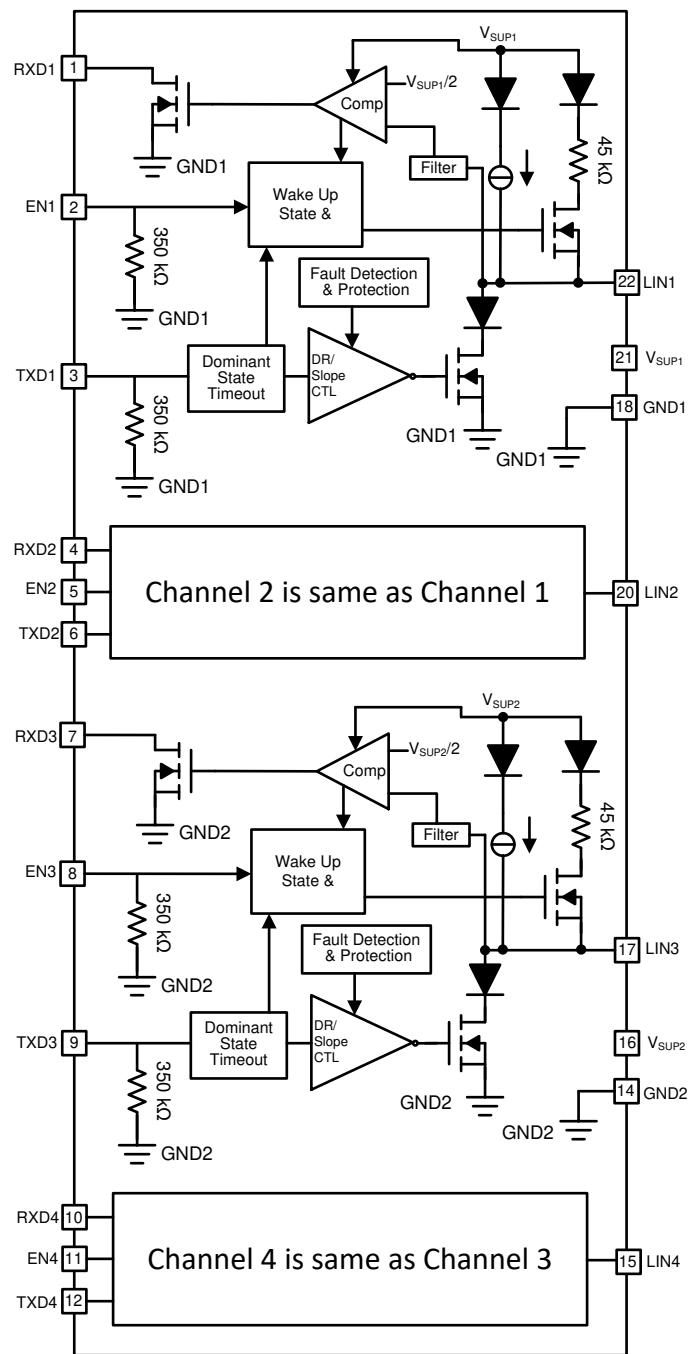
The TLIN2024A-Q1 device is a Quad Local Interconnect Network (LIN) physical layer transceiver, compliant to LIN 2.0, LIN 2.1, LIN 2.2, LIN 2.2A and ISO/DIS 17987–4 standards, with integrated wake-up and protection features. The device has two separate dual LIN transceiver blocks. $V_{SUP1/2}$ provides power to the separate dual transceiver blocks. The LIN bus is a single wire bidirectional bus typically used for low speed in-vehicle networks using data rates up to 20 kbps. The device's LIN receivers work up to 100 kbps supporting in-line programming. The LIN protocol output data stream on the TXD in converted by the device into LIN bus signal using a current-limited wave shaping driver as outlined by the LIN physical layer specification. The receiver converts the data stream to logic level signals that are sent to the microprocessor through the open-drain RXD pin. The LIN bus has two states: dominant state (voltage near ground) and recessive state (voltage near battery). In the recessive state, the LIN bus is pulled high by the internal pull-up resistor (45 k Ω) and a series diode. No external pull-up components are required for responder node applications. Commander node applications require an external pull-up resistor (1 k Ω) plus a series diode per the LIN specification.

The device is designed to support 12-V and 24-V applications with a wide input voltage operating range and also supports low-power sleep mode. The device also provides two methods to wake-up: EN pin and from the LIN bus.

The TLIN2024A-Q1 integrates ESD protection and fault protection which allow for a reduction in the required external components in the applications. In the event of a ground shift or supply voltage disconnection, the device prevents back-feed current through LIN to the supply input. The device also includes undervoltage detection, temperature shutdown protection, and loss-of-ground protection.

V_{SUP1} and GND1 supplies transceivers 1 and 2 while V_{SUP2} and GND2 supplies transceiver 3 and 4. The device is part of the LIN family that includes the TLIN2022A and TLIN2029A LIN transceivers.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 LIN (Local Interconnect Network) Bus

These high voltage input/output pins are single wire LIN bus transmitters and receivers. The LIN pins can survive excessive DC and transient voltages up to 60 V. Reverse currents from the LIN pins to supply ($V_{SUP1/2}$) are minimized with blocking diodes, even in the event of a ground shift or loss of supply ($V_{SUP1/2}$).

9.3.1.1 LIN Transmitter Characteristics

The transmitter has thresholds and AC parameters according to the LIN specification. The transmitter is a low side transistor with and internal current limitation and thermal shutdown. During a thermal shutdown condition, the transmitter is disabled to protect the device. There is an internal pull-up resistor with a serial diode structure.

to $V_{SUP1/2}$, so no external pull-up components are required for the LIN responder node applications. An external pull-up resistor and series diode to $V_{SUP1/2}$ must be added when the device is used for a commander node application.

9.3.1.2 LIN Receiver Characteristics

The receiver characteristic thresholds are proportional with the device supply pin according to the LIN specification.

The receiver is capable of receiving higher data rates (> 100 kbps) than supported by LIN or SAE J2602 specifications. This allows the TLIN2024A-Q1 to be used for high speed downloads at the end-of-line production or other applications. The actual data rate achievable depends on system time constants (bus capacitance and pull-up resistance) and driver characteristics used in the system.

9.3.1.2.1 Termination

There is an internal pull-up resistor with a serial diode structure to $V_{SUP1/2}$, so no external pull-up components are required for the LIN responder node applications. An external pull-up resistor (1 k Ω) and a series diode to $V_{SUP1/2}$ must be added when the device is used for commander node applications as per the LIN specification.

Figure 9-1 shows a commander node configuration and how the voltage levels are defined

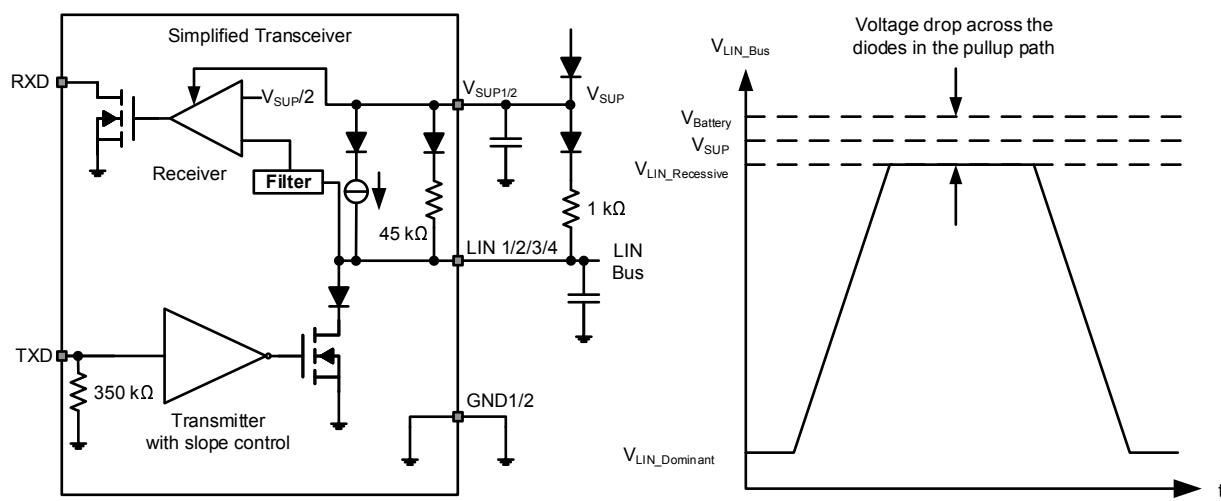


Figure 9-1. Commander Node Configuration with Voltage Levels

9.3.2 TXD (Transmit Input and Output)

TXD is the interface to the processor's LIN protocol controller or SCI/UART that is used to control the state of the LIN output. When TXD is low the LIN output is dominant (near ground). When TXD is high the LIN output is recessive (near $V_{Battery}$). See Figure 9-1. The TXD input structure is compatible with microprocessors with 3.3 V and 5 V I/O. TXD has an internal pull-down resistor. The LIN bus is protected from being stuck dominant through a system failure driving TXD low through the dominant state timeout timer.

9.3.3 RXD (Receive Output)

RXD is the interface to the processor's LIN protocol controller or SCI/UART, which reports the state of the LIN bus voltage. LIN recessive (near $V_{Battery}$) is represented by a high level on the RXD and LIN dominant (near ground) is represented by a low level on the RXD pin. The RXD output structure is an open-drain output stage. This allows the device to be used with 3.3 V and 5 V I/O microprocessors. If the microprocessor's RXD pin does not have an integrated pull-up, an external pull-up resistor to the microprocessor I/O supply voltage is required. In standby mode the RXD pin is driven low to indicate a wake-up request from the LIN bus.

9.3.4 $V_{SUP1/2}$ (Supply Voltage)

$V_{SUP1/2}$ are the power supply pins. $V_{SUP1/2}$ is connected to the battery through an external reverse battery blocking diode (See Figure 9-1). If there is a loss of power at the ECU level, the device has extremely low

leakage from the LIN pin, which does not load the bus down. This is optimal for LIN systems in which some of the nodes are unpowered (ignition supplied) while the rest of the network remains powered (battery supplied).

9.3.5 GND1/2 (Ground)

GND1 and GND2 are the ground connections for LIN1/2 and LIN3/4 channels respectively. V_{SUP1} is referred to GND1 and V_{SUP2} is referred to GND2. The device can operate with a ground shift as long as the ground shift does not reduce $V_{SUP1/2}$ below the minimum operating voltage. If there is a loss of ground at the ECU level, the device has a low leakage from the LIN pin, which does not load the bus down. This is optimal for LIN systems in which some of the nodes are unpowered (ignition supplied) while the rest of the network remains powered (battery supplied).

9.3.6 EN (Enable Input)

EN1, EN2, EN3 and EN4 control the operational modes of the respective LIN channel. When EN1/EN2/EN3/EN4 is high, the LIN1/LIN2/LIN3/LIN4 channel is in normal operating mode allowing a transmission path from TXD to LIN and from LIN to RXD. When either of the EN pins is low, the respective LIN channel is put into sleep mode and there is no transmission path available. The device can enter normal mode only after wake-up. EN has an internal pull-down resistor to ensure the device remains in low power mode even if EN floats.

9.3.7 Protection Features

The TLIN2024A-Q1 has several protection features.

9.3.8 TXD Dominant Time Out (DTO)

During normal mode, if TXD is inadvertently driven permanently low by a hardware or software application failure, the LIN bus is protected by the dominant state timeout timer. This timer is triggered by a falling edge on the TXD pin. If the low signal remains on TXD for longer than t_{DST} , the transmitter is disabled, thus allowing the LIN bus to return to recessive state and communication to resume on the bus. The protection is cleared and the t_{DST} timer is reset by a rising edge on TXD. The TXD pin has an internal pull-down to ensure the device fails to a known state if TXD is disconnected. During this fault, the transceiver remains in normal mode (assuming no change of state request on EN), the transmitter is disabled, the RXD pin reflects the LIN bus and the LIN bus pull-up termination remains on.

9.3.9 Bus Stuck Dominant System Fault: False Wake-Up Lockout

The TLIN2024A-Q1 contains logic to detect bus stuck dominant system faults and prevents the device from waking up falsely during the system fault. Upon entering sleep mode, the device detects the state of the LIN bus. If the bus is dominant, the wake-up logic is locked out until a valid recessive on the bus “clears” the bus stuck dominant, preventing excessive current use. [Figure 9-2](#) and [Figure 9-3](#) show the behavior of this protection.

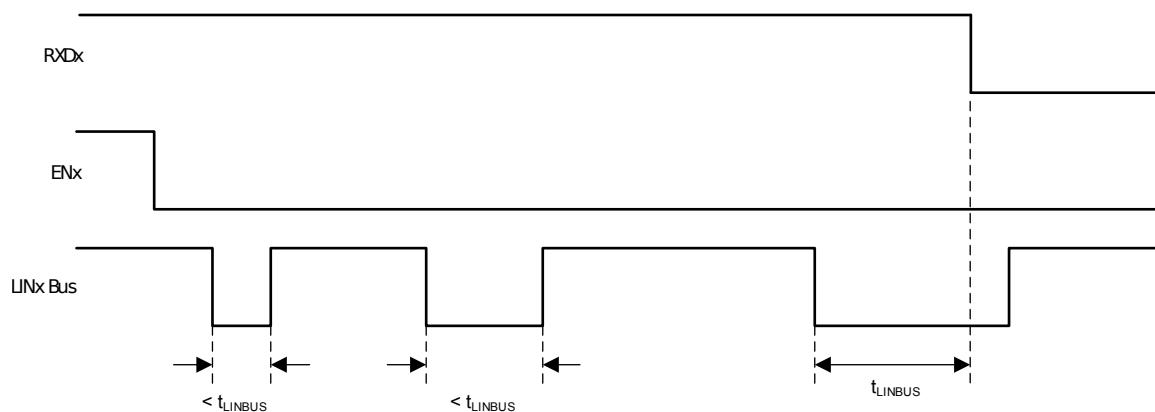


Figure 9-2. No Bus Fault: Entering Sleep Mode with Bus Recessive Condition and Wake-up

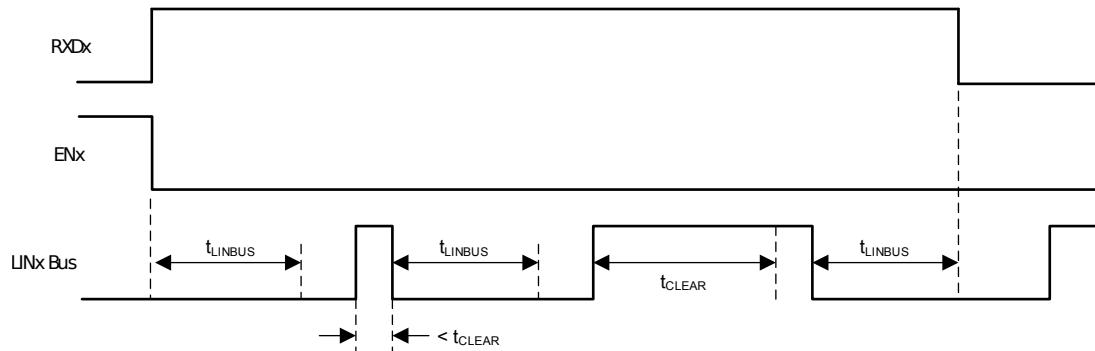


Figure 9-3. Bus Fault: Entering Sleep Mode with Bus Stuck Dominant Fault, Clearing, and Wake-up

9.3.10 Thermal Shutdown

The LIN transmitter is protected by limiting the current; however if the junction temperature of the device exceeds the thermal shutdown threshold, the device puts the LIN transmitter into the recessive state. Once the over temperature fault condition has been removed and the junction temperature has cooled beyond the hysteresis temperature, the transmitter is re-enabled, assuming the device remains in the normal operation mode. During this fault, the transceiver remains in normal mode (assuming no change of state request on EN), the transmitter is in recessive state, the RXD pin reflects the LIN bus and LIN bus pull-up termination remains on.

9.3.11 Under Voltage on V_{SUP}

The TLIN2024A-Q1 contains a power on reset circuit to avoid false bus messages during under voltage conditions when $V_{SUP1/2}$ is less than $UV_{SUP1/2}$.

9.3.12 Unpowered Device and LIN Bus

In automotive applications some LIN nodes in a system can be unpowered (ignition supplied) while others in the network remains powered by the battery. The TLIN2024A-Q1 has a low unpowered leakage current from the bus so an unpowered node does not affect the network or load it down.

9.4 Device Functional Modes

The TLIN2024A-Q1 has three functional modes of operation, normal, sleep, and standby. The next sections describe these modes as well as how the device moves between the different modes. [Figure 9-4](#) graphically shows the relationship while [Table 9-1](#) shows the state of pins.

Table 9-1. Operating Modes

MODE	ENx	RXDx	LIN BUS TERMINATION	TRANSMITTER	COMMENT
Sleep	Low	Floating	Weak Current Pull-up	Off	
Standby	Low	Low	45 kΩ (typical)	Off	Wake-up event detected, waiting on MCU to set EN
Normal	High	LINx Bus Data	45 kΩ (typical)	On	LINx transmission up to 20 kbps

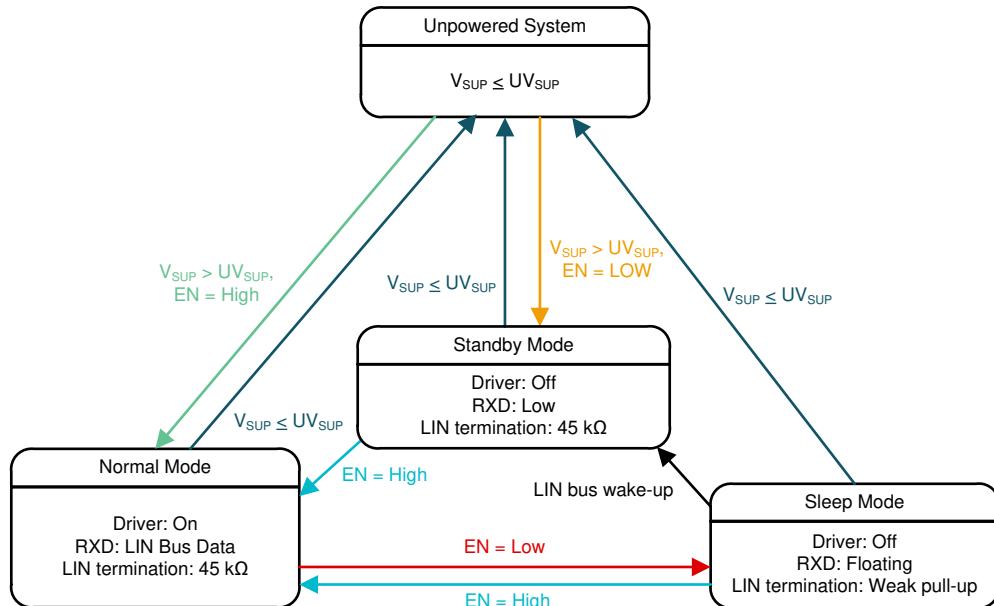


Figure 9-4. Operating State Diagram

9.4.1 Normal Mode

The EN pin controls the mode of the channel. If the EN1/EN2/EN3/EN4 pin is high at power up, the channel powers up in normal mode. In normal operational mode, the receiver and transmitter are active and the LIN transmission up to the LIN specified maximum of 20 kbps is supported. The receiver detects the data stream on the LIN bus and outputs it on RXD for the LIN controller. A recessive signal on the LIN bus is a digital high and a dominant signal on the LIN bus is a digital low. The driver transmits input data from TXD to the LIN bus. Normal mode is entered as EN transitions high while the LIN channel is in sleep or standby mode for $> t_{MODE_CHANGE}$ plus t_{NOMINT} .

9.4.2 Sleep Mode

Sleep Mode is the power saving mode for the TLIN2024A-Q1. Even with extremely low current consumption in this mode, the LIN channel can still wake-up from LIN bus through a wake-up signal or if EN is set high for $> t_{MODE_CHANGE}$. The LIN bus is filtered to prevent false wake-up events. The wake-up events must be active for the respective time periods (t_{LINBUS}).

The sleep mode is entered by setting EN low for longer than t_{MODE_CHANGE} .

While the device is in sleep mode, the following conditions exist.

- The LIN bus driver is disabled and the internal LIN bus termination is switched off (to minimize power loss if LIN is short circuited to ground). However, the weak current pull-up is active to prevent false wake-up events in case an external connection to the LIN bus is lost.
- The normal receiver is disabled.
- EN input and LIN wake-up receiver are active.

9.4.3 Standby Mode

If the device powers up with any of the ENx pins held low, the corresponding LINx channel is in standby mode. Standby mode is also entered whenever a wake-up event occurs through the LIN bus while the device is in sleep mode. The LIN bus responder termination circuit is turned on when standby mode is entered. Standby mode is signaled through a low level on RXD. See [Standby Mode Application Note](#) for more application information.

When EN is set high for longer than t_{MODE_CHANGE} while the device is in standby mode the device returns to normal mode and the normal transmission paths from TXD to LIN bus and LIN bus to RXD are enabled.

9.4.4 Wake-Up Events

There are two ways to wake-up from sleep mode:

- Remote wake-up initiated by the falling edge of a recessive (high) to dominant (low) state transition on LIN bus where the dominant state is held for t_{LINBUS} filter time. After this t_{LINBUS} filter time has been met and a rising edge on the LIN bus going from dominant state to recessive state initiates a remote wake-up event, eliminating false wake-ups from disturbances on the LIN bus or if the bus is shorted to ground.
- Local wake-up through EN being set high for longer than t_{MODE_CHANGE} .

9.4.4.1 Wake-Up Request (RXD)

When the TLIN2024A-Q1 encounters a wake-up event from the LIN bus, RXD goes low and the channel transitions to standby mode until EN is reasserted high and the channel enters normal mode. Once the channel enters normal mode the RXD pin releases the wake-up request signal and the RXD pin then reflects the receiver output from the LIN bus.

9.4.4.2 Mode Transitions

When the TLIN2024A-Q1 is transitioning between modes the device needs the time, t_{MODE_CHANGE} , to allow the change to fully propagate from the EN pin through the device into the new state. When transitioning from sleep or standby mode to normal mode the transition time is the sum of t_{MODE_CHANGE} and t_{NOMINT} .

10 Application and Implementation Disclaimer

Note

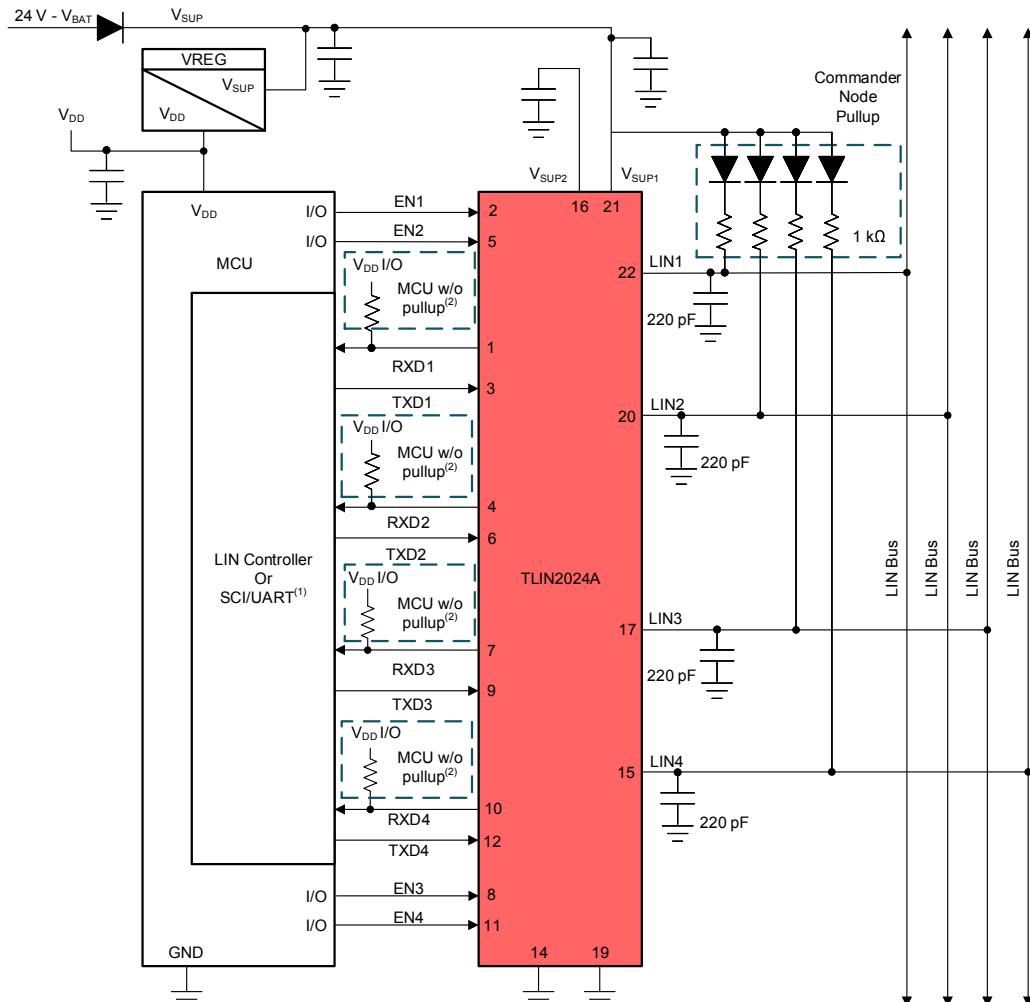
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

10.1 Application Information

The TLIN2024A-Q1 can be used as both a responder device and a commander device in a LIN network. The device comes with the ability to support both remote wake-up request and local wake-up request.

10.2 Typical Application

The device comes with an integrated 45 kΩ pull-up resistor and series diode for responder node applications. For commander node applications, an external 1 kΩ pull-up resistor with series blocking diode can be used. [Typical LIN Bus](#) shows the device being used in both commander and responder applications.



- (1) If RXD on MCU, or LIN transceiver, has an internal pull-up, then an external pull-up resistor is not required.
- (2) If RXD on MCU, or LIN transceiver, does not have an internal pull-up, then an external pull-up resistor is required.
- (3) Commander node applications require an external 1 kΩ pull-up resistor and serial diode.
- (4) Decoupling capacitor values are system dependent but usually have 100 nF, 1 µF and $\geq 10 \mu F$

Figure 10-1. Typical LIN Bus

10.2.1 Design Requirements

The RXD output structure is an open-drain output stage. This allows the TLIN2024A-Q1 to be used with 3.3 V and 5 V I/O microprocessors. If the RXD pin of the microprocessor does not have an integrated pull-up, an external pull-up resistor to the microprocessor I/O supply voltage is required.

The $V_{SUP1/2}$ pins of the device should be decoupled with a 100 nF capacitor as close to the supply pin on the device as possible. The system should include additional decoupling on the V_{SUP} line as needed per the application requirements.

10.2.1.1 Detailed Design Procedures

10.2.1.2 Normal Mode Application Note

When using the TLIN2024A-Q1 in systems which are monitoring the RXD pin for a wake-up request, special care should be taken during the mode transitions. The output of the RXD pin is indeterminate for the transition period between states as the receivers are switched. The application software should not look for an edge on the RXD pin indicating a wake-up request until t_{MODE_CHANGE} when going from sleep or standby to normal mode. This is shown in [Mode Transitions](#)

10.2.1.3 Standby Mode Application Note

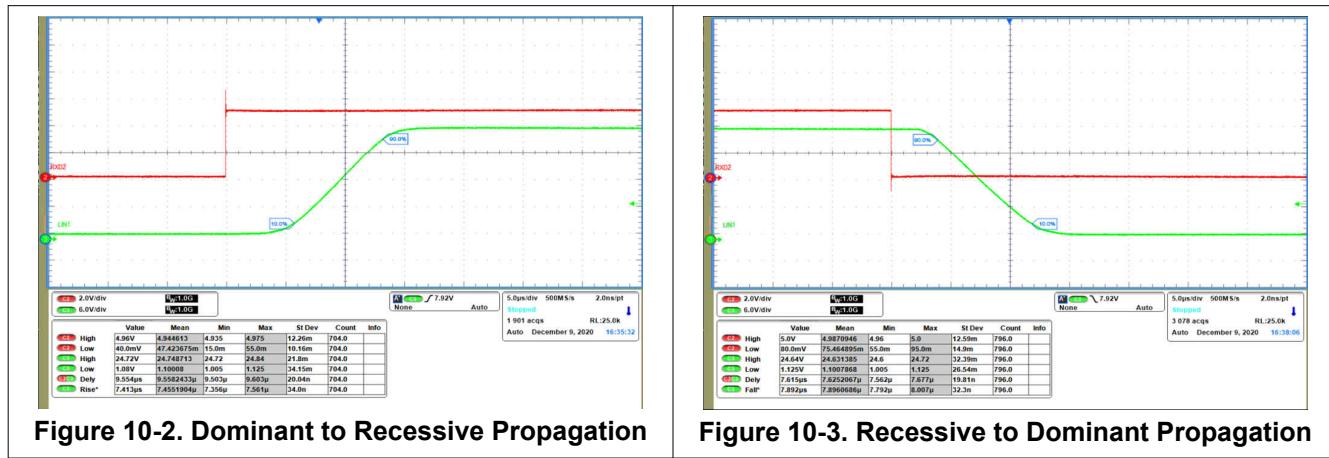
If the TLIN2024A-Q1 detects an under voltage on $V_{SUP1/2}$, the RXD pin transitions low and would signal to the software that the device is in standby mode and should be returned to sleep mode for the lowest power state.

10.2.1.4 TXD Dominant State Timeout Application Note

The maximum dominant TXD time allowed by the TXD dominant state time out limits the minimum possible data rate of the device. The LIN protocol has different constraints for commander and responder applications thus there are different maximum consecutive dominant bits for each application case and thus different minimum data rates.

10.2.2 Application Curves

Figure 10-2 and Figure 10-3 show the propagation delay from the TXD pin to the LIN pin for both dominant to recessive and recessive to dominant edges. Waveforms are for 1 channel of the device configured in commander mode with external pull-up resistor (1 kΩ) and 680 pF bus capacitance.



10.3 Power Supply Recommendations

The TLIN2024A-Q1 was designed to operate directly off a car battery, or any other DC supply ranging from 4 V to 48 V. A 100 nF decoupling capacitor should be placed as close to the $V_{SUP1/2}$ pin of the device as possible. It is good practice for some applications with noisier supplies to include 1 μ F and 10 μ F decoupling capacitor.

10.4 Layout

In order for the PCB design to be successful, start with the design of the protection and filtering circuitry. Because ESD and EFT transients have a wide frequency bandwidth from approximately 3 MHz to 3 GHz, high frequency layout techniques must be applied during PCB design. Placement at the connector also prevents these noisy events from propagating further into the PCB and system.

10.4.1 Layout Guidelines

- Pins 1, 4, 7 and 10 (RXD1/2/3/4):** The pins are open drain outputs and require an external pull-up resistor in the range of 1 kΩ and 10 kΩ to function properly. If the microprocessor paired with the transceiver does not have an integrated pull-up, an external resistor should be placed between RXD and the regulated voltage supply for the microprocessor.
- Pins 2, 5, 8 and 11 (EN1/2/3/4):** EN is an input pin that is used to place the device in a low power sleep mode. If this feature is not used the pin should be pulled high to the regulated voltage supply of the microprocessor through a series resistor, values between 1 kΩ and 10 kΩ. Additionally, a series resistor may be placed on the pinto limit current on the digital lines in the case of an over voltage fault.
- Pin 13, 18, 23 and 24 (NC):** Not Connected
- Pins 3, 6, 9 and 12 (TXD1/2/3/4):** The TXD pins are the transmitter input signals to the device from the microprocessor. A series resistor can be placed to limit the input current to the device in the case of an overvoltage on this pin. A capacitor to ground can be placed close to the input pin of the device to filter noise.
- Pin 14, 19 (GND2/1):** This is the ground connection for the device. This pin should be tied to the ground plane through a short trace with the use of two vias to limit total return inductance.
- Pins 22, 20, 17 and 15 (LIN1/2/3/4):** This pin connects to the LIN bus. For responder node applications a 220 pF capacitor to ground is implemented. For commander node applications and additional series resistor and blocking diode should be placed between the LIN pin and the $V_{SUP1/2}$ pin.
- Pin 21, 160 ($V_{SUP1/2}$):** This is the supply pin for the device. A 100 nF decoupling capacitor should be placed as close to the device as possible.

Note

All ground and power connections should be made as short as possible and use at least two vias to minimize the total loop inductance.

10.4.2 Layout Example

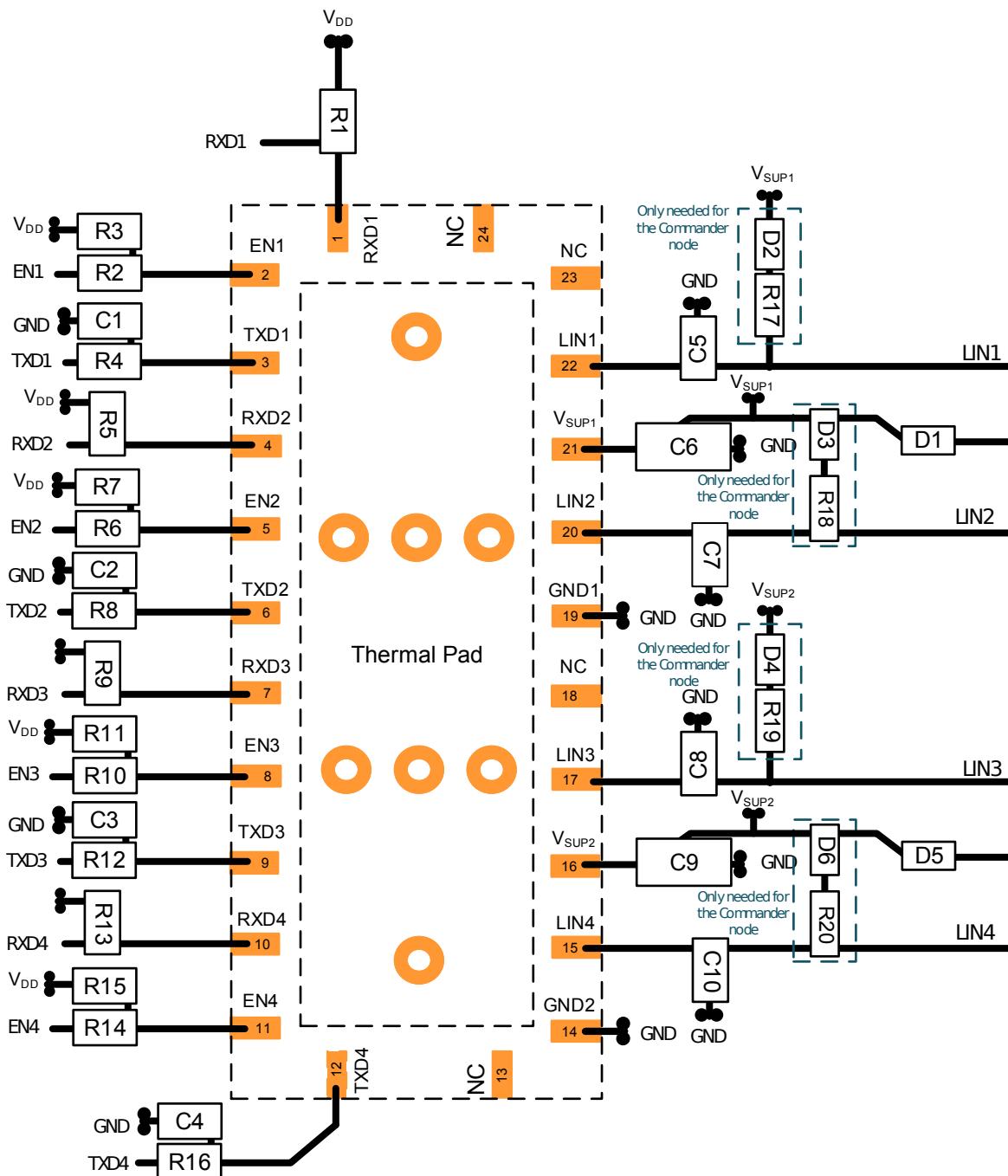


Figure 10-4. Layout Example

11 Device and Documentation Support

11.1 Documentation Support

This device will conform to the following LIN standards. The core of what is needed is covered within this system spec, however reference should be made to these standards and any discrepancies pointed out and discussed. This document should provide all the basics of what is needed.

11.1.1 Related Documentation

For related documentation see the following:

LIN Standards:

- ISO/DIS 17987-1: Road vehicles -- Local Interconnect Network (LIN) -- Part 1: General information and use case definition
- ISO/DIS 17987-4: Road vehicles -- Local Interconnect Network (LIN) -- Part 4: Electrical Physical Layer (EPL) specification 12V/24V
- SAE J2602-1: LIN Network for Vehicle Applications

EMC requirements:

- SAE J2962-1
- ISO 10605: Road vehicles - Test methods for electrical disturbances from electrostatic discharge
- ISO 11452-4:2011: Road vehicles - Component test methods for electrical disturbances from narrowband radiated electromagnetic energy - Part 4: Harness excitation methods
- ISO 7637-1:2015: Road vehicles - Electrical disturbances from conduction and coupling - Part 1: Definitions and general considerations
- ISO 7637-3: Road vehicles - Electrical disturbances from conduction and coupling - Part 3: Electrical transient transmission by capacitive and inductive coupling via lines other than supply lines
- IEC 62132-4:2006: Integrated circuits - Measurement of electromagnetic immunity 150 kHz to 1 GHz - Part 4: Direct RF power injection method
- IEC 6100-4-2
- IEC 61967-4
- CISPR25

Conformance Test requirements:

- ISO/DIS 17987-7: Road vehicles -- Local Interconnect Network (LIN) -- Part 7: Electrical Physical Layer (EPL) conformance test specification
- SAE J2602-2: LIN Network for Vehicle Applications Conformance Test

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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11.4 Trademarks

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11.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLIN2024ARGYRQ1	Active	Production	VQFN (RGY) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TL2024A
TLIN2024ARGYRQ1.A	Active	Production	VQFN (RGY) 24	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TL2024A

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

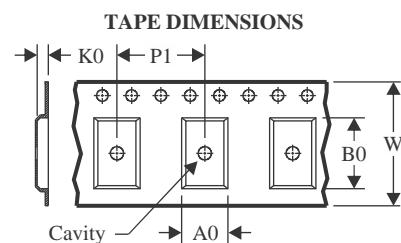
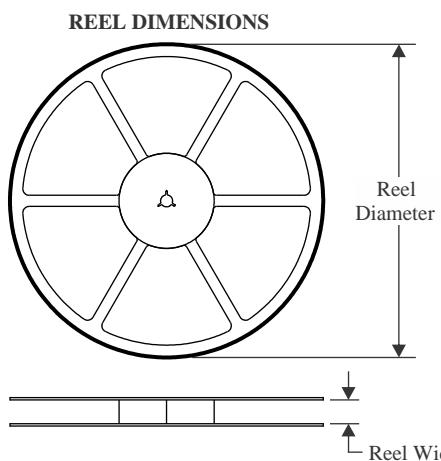
⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

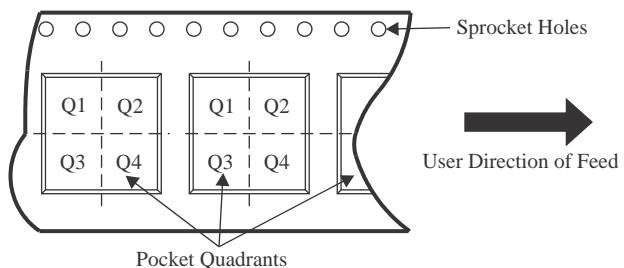
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

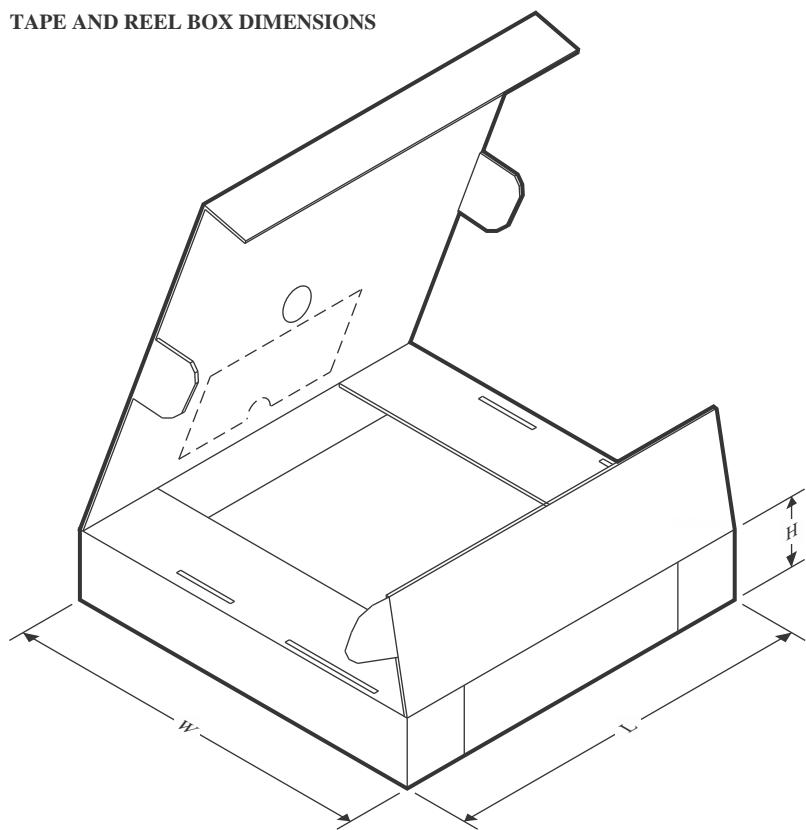
TAPE AND REEL INFORMATION


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLIN2024ARGYRQ1	VQFN	RGY	24	3000	330.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLIN2024ARGYRQ1	VQFN	RGY	24	3000	367.0	367.0	35.0

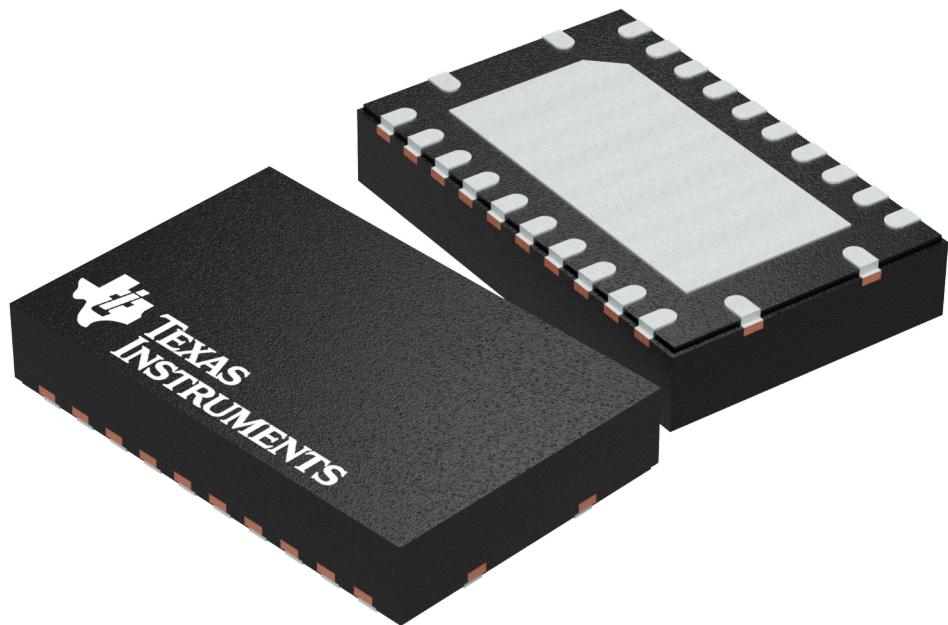
GENERIC PACKAGE VIEW

RGY 24

5.5 x 3.5 mm, 0.5 mm pitch

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

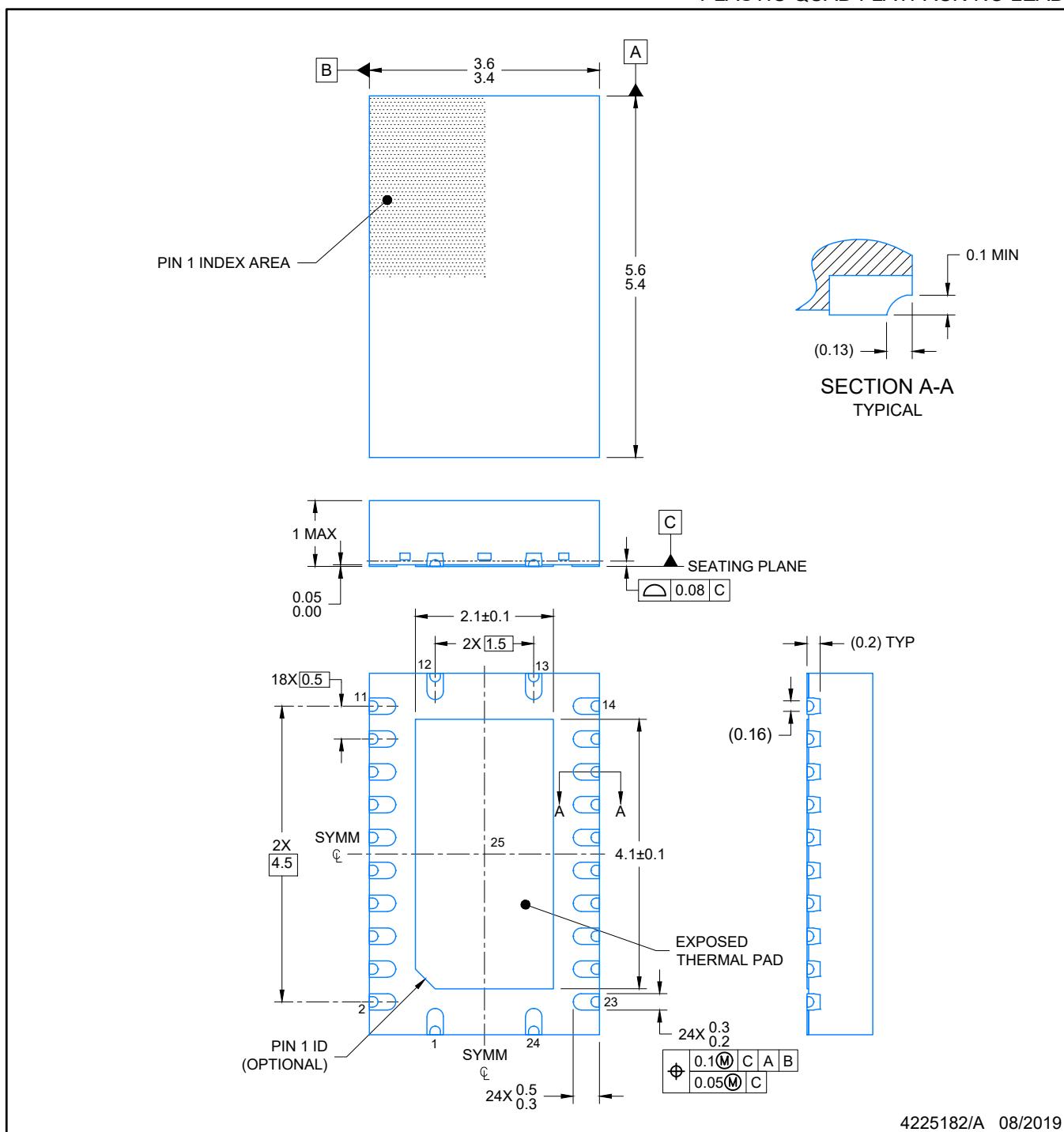
4203539-5/J

PACKAGE OUTLINE

VQFN - 1 mm max height

RGY0024E

PLASTIC QUAD FLATPACK-NO LEAD



4225182/A 08/2019

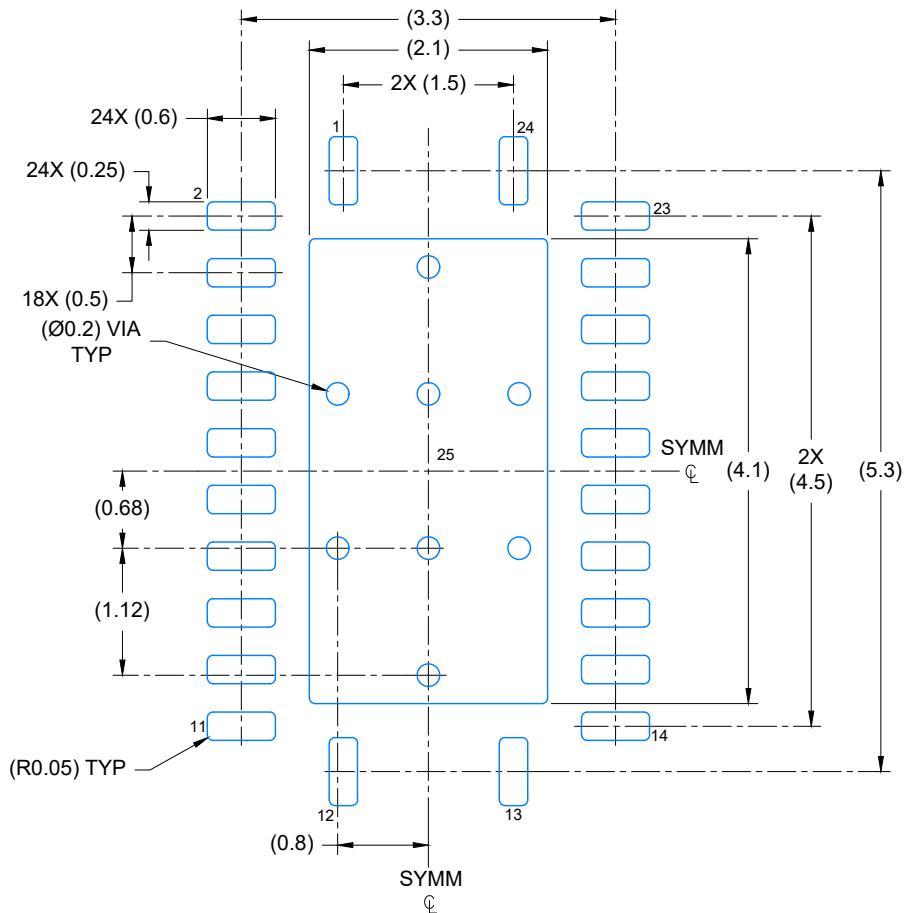
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

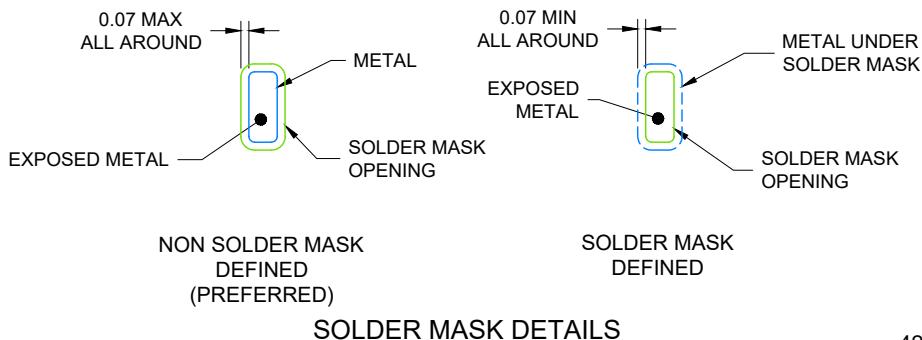
EXAMPLE BOARD LAYOUT

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK-NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



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NOTES: (continued)

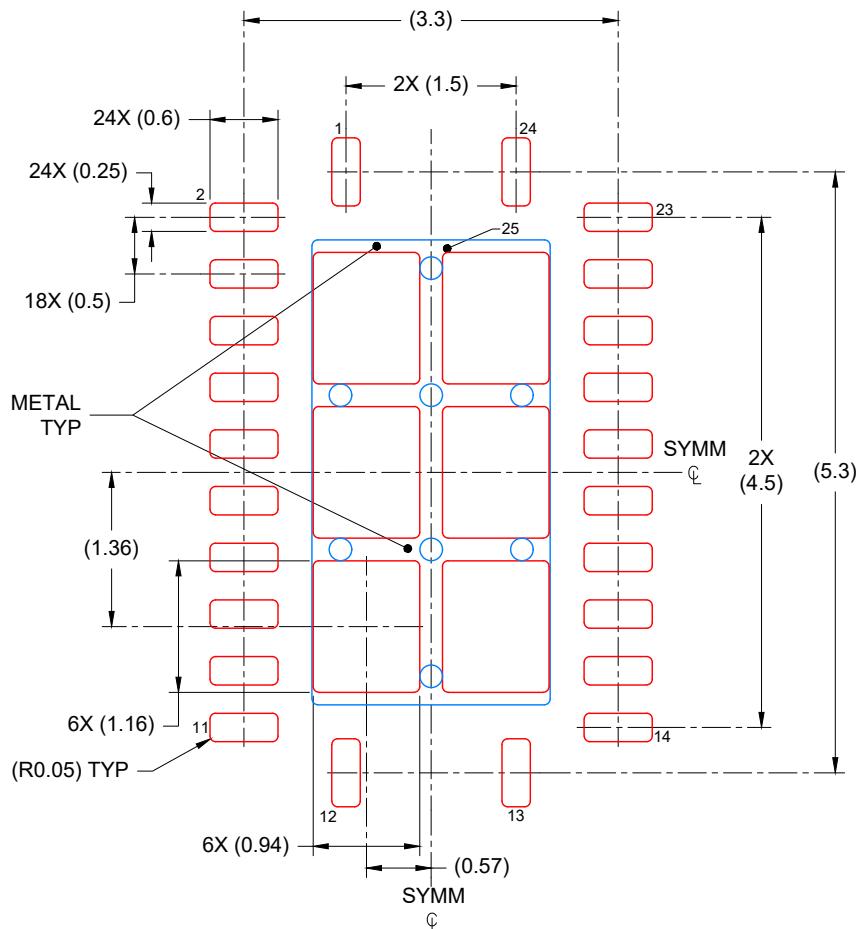
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK-NO LEAD

RGY0024E



SOLDER PASTE EXAMPLE BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
76% PRINTED COVERAGE BY AREA
SCALE: 15X

4225182/A 08/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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